

Impact of Josephson Junction Array Modes on Fluxonium Readout

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Dispersive readout of superconducting qubits is often limited by readout-drive-induced unwanted transitions between qubit levels. While there is a growing understanding of such effects in transmon qubits, the case of highly nonlinear fluxonium qubits is more complex. We theoretically analyze measurement-induced state transitions (MIST) during the dispersive readout of a fluxonium qubit, focusing on a new mechanism: a simultaneous transition/excitation involving the qubit and an internal mode of the Josephson junction array in the fluxonium circuit. Using an adiabatic Floquet approach, we show that these new kinds of MIST processes are relevant with realistic circuit parameters and relatively low readout drive powers compared to the admissible range of signal-to-noise ratio. They also contribute to excess qubit dephasing even after a measurement is complete. We also investigate the dependence of such transitions on the circuit parameters. [ER: We find that with a judicious choice of frequency allocations or coupling strengths, these parasitic processes can most likely be avoided.]

I. INTRODUCTION

The fluxonium superconducting qubit, based on a Josephson junction shunted by a capacitor and a large inductance, has emerged as a promising platform for quantum information. It exhibits long lifetimes [1–4], and both single [5] and two-qubit gates [6, 7] have been demonstrated with high fidelity, with potential room for even further improvements [8–12]. The inductive shunt is a crucial part of the fluxonium circuit, with the most common realization being a Josephson junction array (JJA). In regimes where internal array modes are not excited, the JJA can act as a linear superinductance (see e.g. [13, 14]).

The ability to make fast and efficient measurements is equally crucial, in addition to coherence and the ability to do high-fidelity gates, for any qubit platform. Similar to other superconducting qubits, dispersive readout (using a driven readout resonator) has been the standard choice for fluxonium readout (see e.g. [5]). While such measurement schemes should ideally be quantum non-demolition (QND) [15], several experiments have reported non-QND backaction (either enhanced relaxation or transitions to non-computational states) during fluxonium readout [6, 16–18]. Recent theoretical work on driven transmon qubits has provided insights into these so-called measurement-induced state transitions (MIST), showing that multi-photon transitions can lead to resonant excitation of the transmon to higher levels (see e.g. [19–24]).

Similar detrimental transitions need examination with fluxonium, to find ways to suppress such effects. The fluxonium circuit is fundamentally different and needs independent analysis. For example, the enhanced nonlinearity can dramatically change the num-

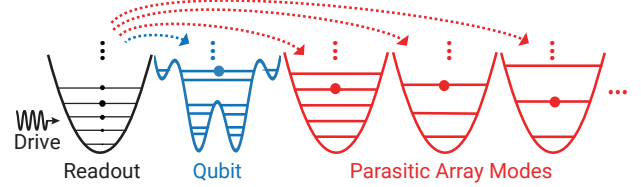


FIG. 1. **Schematic of a PMIST process.** A parasitic effect where energy in a coherent state of the driven readout mode (black) excites extraneous linear modes (red) and the nonlinear qubit mode (blue) simultaneously.

ber and likelihood of potential transitions [20, 25]. In this article, we provide a comprehensive analysis of a unique MIST mechanism in fluxonium that arises due to the internal modes of the JJA during fluxonium readout (see Fig. 1). We show that for realistic parameters and drive powers, deleterious resonant processes that simultaneously excite the qubit and an internal mode can occur. We term these processes parasitic MIST or PMIST. This work can be viewed as an example of a more general problem: how is the physics of MIST modified in the presence of a structured environment?

We focus on a heavy fluxonium qubit operated at its flux sweet spot (cf Fig. 2) and investigate MIST, considering the coupling to the most relevant JJA internal modes. We treat the readout as an effective classical drive on the fluxonium-plus-JJA system and use an adiabatic Floquet branch analysis to identify dominant MIST processes. This method was used for transmon studies in Refs. [22, 23]. We also validate this approach through full time-dependent simulations. Our work goes beyond showing that such processes could be relevant. We discuss how they provide a mechanism for degrading qubit coherence even after measurements are complete (via dephasing from dispersive couplings to the excited internal modes). We also discuss how alternate circuit de-

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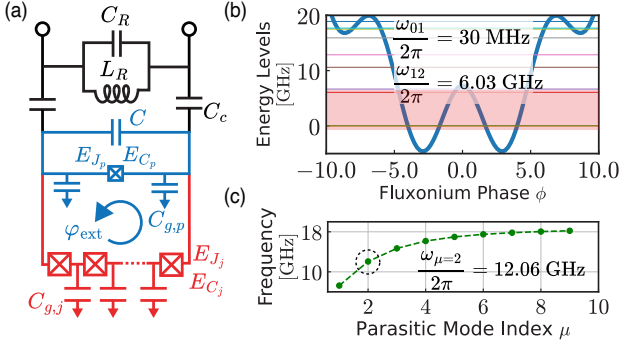


FIG. 2. **Fluxonium readout circuit, qubit, and array modes' spectrum.** (a) The color scheme shows primary components that correspond to various modes, shown in Fig. 1 when a JJA fluxonium circuit is connected to a readout resonator (R). The subscripts p, j denote components of the phase-slip junction and the JJA, respectively. This circuit shows coupling capacitances (C_c), readout frequency parameters ($\omega_r = 1/\sqrt{L_R C_R}$), parasitic ground capacitances in JJA ($C_{g,j}$) and next to the phase-slip junction ($C_{g,p}$). The differential capacitance C adjusts the charging energy of the qubit mode (see Table II). (b) Fluxonium mode energy levels in units of h , with the highlighted area showing the first three levels essential for certain readout schemes [5]. (c) Parasitic mode frequencies $\omega_{\mu}/2\pi$. The lowest even mode $\mu = 2$ has the strongest coupling to the qubit (see Fig. 11).

signs affect PMIST processes, focusing on how modifications affect the parasitic mode to qubit coupling strengths. Our analysis suggests that in optimizing fluxonium readout, parasitic JJA modes introduce additional constraints on the circuit design. We stress that our analysis is not an exhaustive study of MIST effects in fluxonium readout but aims to show how new mechanisms involving internal JJA degrees of freedom arise in realistic setups.

The remainder of this article is structured as follows. Sec. II analyzes the full circuit, including fluxonium, JJA, and readout resonator. Using a standard harmonic approximation [26], we derive qubit-parasitic mode coupling strengths and lower-bound parasitic mode effects during readout. Sec. III analyzes readout dynamics, including MIST processes and dephasing from parasitic modes. Sec. IV examines the effects of varying coupling strengths between the qubit and a JJA internal mode on PMIST and investigates different ranges of readout frequencies and parasitic mode frequencies using an energy-conservation picture. In the concluding Sec. V, we discuss directions for future work.

N	φ_{ext}	E_{J_p}	E_{C_p}	E_C	E_{J_j}	E_{C_j}	$E_{C_{g,j}}$	$E_{C_{g,p}}$	E_{C_c}
122	$0.5\Phi_0$	7.30	6.12	1.73	60	0.74	194	1.94	19.40

TABLE I. **Circuit parameters for Fig. 2(a) inspired by Ref. [5].** All energies are given in GHz. Here $\Phi_0 = h/2e$ denotes the magnetic flux quantum. The capacitive energies $E_{C'} = \frac{19.4}{C'(\text{fF})}$ GHz are computed from the corresponding capacitances C' . See Table IV in App. B for the values of capacitances.

II. FLUXONIUM READOUT CIRCUIT

We consider a JJA-fluxonium circuit dispersively coupled to a readout mode as shown in Fig. 2. We choose circuit parameters (as listed in Table I) motivated by recent experiments on heavy fluxonium [5–7]. We also restrict attention to the flux “sweet spot” that maximizes qubit coherence. This choice is expected to reduce the number of allowed transitions in the circuit, as transitions between parity-conserving states via first-order processes are forbidden in this case. For our parameters, the qubit frequency ($\omega_{01}/2\pi$) is ~ 30 MHz and the plasmon frequency (i.e., splitting frequency between first and second qubit excited states $\omega_{12}/2\pi$) is ~ 6 GHz (see Table II for a full list of readout parameters).

Our work specifically investigates the role of the JJA, which comprises the inductive shunt of the fluxonium. The array comprises N junctions and $N - 1$ ground capacitances (C_{g_n}) [27]. We neglect disorder effects and take junction parameters and parasitic ground capacitances to be uniform in the array (i.e., $C_{g_1} = \dots = C_{g_N}$). This capacitance value is given by $C_{g,j}$, where the subscript j indicates the parasitic ground capacitance in the JJA [28]. As shown in Fig. 2(a), two additional identical ground capacitances C_{g_0}, C_{g_N} near the phase-slip junctions in blue (see Fig. 2) may have different values compared to those in the interior of the array, i.e., $C_{g_0} = C_{g_N} \equiv C_{g,p} \neq C_{g,j}$. Note that the subscript p indicates the parasitic ground capacitances next to the phase-slip junction.

The JJA fluxonium circuit has N internal degrees of freedom [26, 29]: one qubit mode (ϕ) and $N - 1$ internal modes ($\mu = 1, 2, \dots, N - 1$). These internal modes are coupled via the ground capacitances and are referred to as the “parasitic” modes of the JJA.

In our notation, we label the readout mode as r . The charge and flux quadratures of the qubit mode are denoted by \hat{N}_ϕ and $\hat{\phi}$ where $[\hat{\phi}, \hat{N}_\phi] = i\hbar$.

We simplify the problem by treating all but the qubit mode as harmonic oscillators; this is a good approximation for standard device parameters [23, 26, 29]. We denote the photon loss and gain operators of the linear modes r, μ using \hat{a}_r, \hat{a}_μ and $\hat{a}_r^\dagger, \hat{a}_\mu^\dagger$, respectively.

Setting $\hbar = 1$, the Hamiltonian of our fluxonium circuit has the form [26]

$$\hat{H} = \hat{H}_\phi + \hat{H}_\mu + \hat{H}_r + \hat{H}_{\text{int}}, \quad (1)$$

where the qubit Hamiltonian \hat{H}_ϕ (with JJA inductive energy $E_L = E_{J_j}/N$) is

$$\hat{H}_\phi/2\pi = 4\tilde{E}_c^\phi \hat{N}_\phi^2 + E_{J_p} \cos \hat{\phi} + E_L \hat{\phi}^2/2, \quad (2)$$

the junction array and readout Hamiltonians are $\hat{H}_\mu = \sum_\mu \omega_\mu \hat{a}_\mu^\dagger \hat{a}_\mu$ and $\hat{H}_r = \omega_r \hat{a}_r^\dagger \hat{a}_r$, respectively. The qubit charging energy \tilde{E}_c^ϕ (see Table II) deviates from the target value of $E_{C_c}^\phi = 1$ GHz due to parasitic capacitance. The coupling between the three modes is

Qubit (ϕ) & Readout (r)	$\omega_{01}/2\pi$	$\omega_{12}/2\pi$	\tilde{E}_c^ϕ	$g_{\phi r}/2\pi$	$\chi_{\phi r}(01)/2\pi$	$\chi_{\phi r}(12)/2\pi$	$\omega_r/2\pi$	$\kappa_r/2\pi$
	30 MHz	6.04 GHz	0.92 GHz	25.50 MHz	0.18 MHz	0.98 MHz	8.50 GHz	1 MHz
Parasitic-Mode ($\mu = 2$)			$g_{\phi\mu}/2\pi$	$g_{\mu r}/2\pi$	$\chi_{\phi\mu}(01)/2\pi$	$\chi_{\phi\mu}(12)/2\pi$	$\omega_\mu/2\pi$	Q_μ
			157 MHz	4.22 MHz	-1.10 MHz	5 MHz	12.06 GHz	10^4

TABLE II. **Measurement parameters for qubit mode ϕ , readout mode r , and closest even parasitic mode $\mu = 2$.** All quantities are derived and computed analytically using circuit parameters listed in Table I (see Apps. A-B for details). **Qubit-Readout Parameters:** (ω_{ij}) qubit $i \rightarrow j$ splitting frequency between fluxonium excited states i, j ; (\tilde{E}_c^ϕ) qubit charging energy; ($g_{\phi r}$) qubit-readout coupling; ($\chi_{\phi r}(ij)$) dispersive shift due to readout mode in the two-level ij system; (ω_r) readout mode frequency; (κ_r) decay rate of the readout resonator. **Parasitic-Mode Parameters:** ($g_{\phi\mu}$) qubit-parasitic coupling; ($g_{\mu r}$) parasitic-readout coupling; ($\chi_{\phi\mu}(ij)$) dispersive shift due to parasitic mode μ in the two-level ij system; (ω_μ) mode frequency; and (Q_μ) internal quality factor inspired by [13].

described by the interaction Hamiltonian

$$\begin{aligned} \hat{H}_{\text{int}} = & -i \sum_{\mu} g_{\phi\mu} \frac{\hat{N}_{\phi}}{N_{\phi, \text{ZPF}}} (\hat{a}_{\mu} - \hat{a}_{\mu}^{\dagger}) \\ & - i g_{\phi r} \frac{\hat{N}_{\phi}}{N_{\phi, \text{ZPF}}} (\hat{a}_r - \hat{a}_r^{\dagger}) \\ & - \sum_{\mu} g_{\mu r} (\hat{a}_r - \hat{a}_r^{\dagger}) (\hat{a}_{\mu} - \hat{a}_{\mu}^{\dagger}). \end{aligned} \quad (3)$$

For our parameters, the zero-point fluctuations of qubit charge are $N_{\phi, \text{ZPF}} = 0.36$. Values for all remaining parameters are given in Table II. Explicit expressions for the $g_{\phi\mu}$ are discussed in Sec. IV.

We find that the lowest-frequency even parasitic mode $\mu = 2$ has the strongest coupling to the qubit mode (see Fig. 11 in App. B1); corresponding parameters are listed in Table II. The symmetry of the circuit in Fig. 2(a) prevents coupling between all odd parasitic modes (including $\mu = 1$) and other circuit modes [26]. For completeness, we derive the Lagrangian of the symmetric circuit to prove this result in App. A. In addition, we derive the Lagrangian for an asymmetric circuit with a different grounding configuration, inspired by [5]. We show that this asymmetric circuit couples the lowest frequency parasitic mode $\mu = 1$, which is likely even more detrimental for PMIST. Surprisingly, Fig. 11 shows that the $\mu = 2, 4, 6$ parasitic modes couple to the qubit with a strength $g_{\phi\mu}$ that is stronger than the qubit-readout coupling $g_{\phi r}$.

Given these insights, in the rest of this work, we focus on the symmetric circuit from Fig. 2 using parameters given by Tables I-II in Eq. 1. Further, our description retains only the strongest coupled parasitic mode $\mu = 2$, along with the qubit and readout resonator. For details on other parasitic modes and their parameters, see App. B1. Note that for our chosen parameters (see Table I), the qubit couples roughly six times more strongly to the parasitic mode at $\mu = 2$ than it does to the readout r [30]. This strong coupling implies that the parasitic mode can play a significant role in measurement-induced state transitions, i.e., the PMIST effect that is the subject of this work.

III. PARASITIC-MODE-INDUCED STATE TRANSITIONS: PMIST

In this section, we analyze how the presence of a parasitic mode ($\mu = 2$) affects the dynamics of a driven fluxonium circuit during a readout pulse. To simulate the linear drive on the readout resonator, we add a drive term $\hat{V}_d = i\xi(\hat{a}_r - \hat{a}_r^{\dagger}) \cos \omega_d t$ to the system Hamiltonian in Eq. 1. Considering the fluxonium qubit mode, parasitic modes, and readout resonator, a full numerical analysis of several excitations in the circuit would require a prohibitively large Hilbert space. To truncate our Hilbert space to feasible dimensions for numerical simulations, we include only a single parasitic mode $\mu = 2$ (as previously justified in Sec. II) and replace the readout mode with a classical drive term [20, 22, 23] (see derivation in App. C2). Under this semi-classical approximation, the driven circuit Hamiltonian includes the qubit mode ϕ and the parasitic mode at $\mu = 2$, and is

$$\hat{H}_{\text{s.c.}}(\bar{n}_r) = \hat{H}_0 + \hat{V}_{\text{s.c.}}(\bar{n}_r). \quad (4)$$

Here, the bare Hamiltonian is

$$\hat{H}_0 = \hat{H}_{\phi} + \hat{H}_{\mu} + \frac{g_{\phi\mu} \hat{N}_{\phi} \hat{N}_{\mu}}{N_{\phi, \text{ZPF}} N_{\mu, \text{ZPF}}} \quad (5)$$

and the modified drive term $V_{\text{s.c.}}$ is

$$\hat{V}_{\text{s.c.}}(\bar{n}_r) = \frac{\xi_{\phi r}(\bar{n}_r)}{N_{\phi, \text{ZPF}}} \hat{N}_{\phi} \cos \omega_d t + \frac{\xi_{\mu r}}{N_{\mu, \text{ZPF}}}(\bar{n}_r) \hat{N}_{\mu} \cos \omega_d t, \quad (6)$$

where the effective drive amplitudes $\xi_{\mu(\phi)r}(\bar{n}_r) = 2g_{\mu(\phi)r} \sqrt{\bar{n}_r}$, and \bar{n}_r denotes the average number of photons in the readout cavity. In the remaining text, we refer to the quantities $\xi_{\phi r/\mu r}$ as “qubit drive strengths” and “parasitic drive strengths”, respectively.

Our primary focus is to analyze PMIST processes that introduce simultaneous transitions in the parasitic mode and the qubit mode. To identify the likely state transitions in the driven circuit, we first examine the energy eigenstates of the bare Hamiltonian \hat{H}_0 in Eq. 5. These states are hybridized fluxonium-parasitic mode states, and we label them as $|\tilde{k}, \tilde{n}\rangle$. A given state $|\tilde{k}, \tilde{n}\rangle$ corresponds to the eigenstate that has the maximum overlap with “bare” fluxonium and parasitic mode states $|k\rangle_{\phi} \otimes |n\rangle_{\mu}$, i.e., the eigenstates of H_{ϕ} and H_{μ} .

In what follows, we identify relevant state transitions in the driven fluxonium plus parasitic mode system. First, we perform an analysis based on the Floquet eigenstates of our system at a given fixed drive power [21–23]. We then simulate the drive ring-up to some chosen final photon number \bar{n}_r and identify potential state transitions. We do this for a range of drive frequencies ω_d . We find that the presence of the parasitic mode $\mu = 2$ significantly increases the number of MIST processes in the system. We analyze the processes that cause these transitions and quantify their rates using perturbative approaches and Landau-Zener probability calculations [31]. We also show that the residual population in the parasitic modes, after a readout pulse, can lead to significant dephasing of the reset qubit mode, limiting the performance of the qubit for future use.

A. Floquet branch analysis method

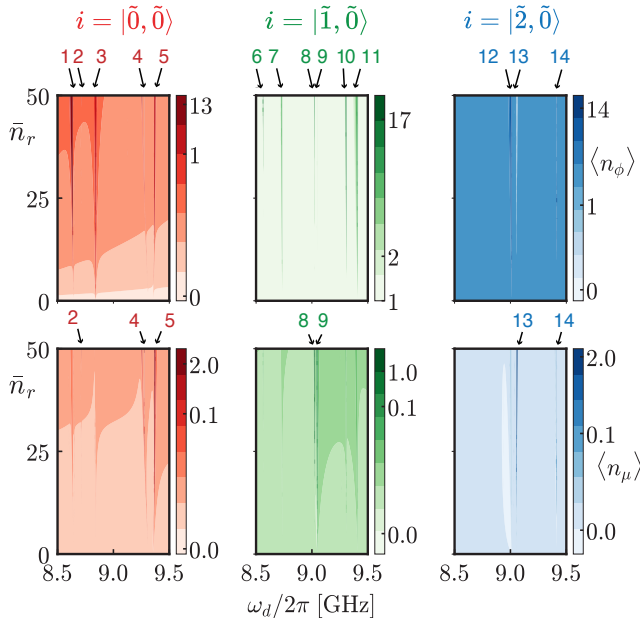


FIG. 3. MIST and PMIST processes as seen in Floquet branch simulations. Each column corresponds to the branch associated with a specific undriven (but dressed) eigenstate $i = |\tilde{k}, \tilde{0}\rangle$. **Top row:** Average fluxonium excitation number in the given branch $\langle n_\phi \rangle$, as a function of drive power ($\propto \bar{n}_r$) and drive frequency ω_d . **Bottom row:** Average excitation number of the $\mu = 2$ parasitic mode, $\langle n_\mu \rangle$. Color scales use a log scaling to help visualize all transitions. Arrows and numbers indicate each transition (with numbers corresponding to Table III). See Figs. 21–23 of App. C 3 b for corresponding behavior of quasienergies.

Our first numerical analysis involves calculating the Floquet eigenstates of $H_{s.c.}$ (see Eq. 4) for various fixed values of the drive powers, as controlled by the average photon number \bar{n}_r . We do this by retaining the lowest 20 levels in the qubit subspace ϕ and 5 levels in the parasitic mode $\mu = 2$ [32]; the truncation for this analysis is discussed further in App. C 1. Our goal is to use these results to make predictions

for a readout pulse involving a time-dependent drive power, identifying possible transitions starting from a dressed state $|i\rangle = |\tilde{\phi}, \tilde{\mu}\rangle$ where $\phi \in \{0, 1, 2\}$ and $\mu = 0$ (i.e., the parasitic mode is initially empty). With $\omega_\mu/2\pi = 12.06$ GHz, the analysis in this section considers the regime of negative detuning where $\omega_{\mu=2} > \omega_d = \omega_r \gg \omega_q$, and can be replicated for any other parasitic mode $\mu \neq 2$. Note that we also analyze the effects of an alternative circuit with $\omega_{\mu=2}/2\pi \sim 16$ GHz and $\omega_{01}/2\pi \sim 300$ MHz in Sec. IV.

Inspired by [22, 23], we extract PMIST processes by tracking the evolution of the Floquet eigenstates as we increase the parameter \bar{n}_r , a method known as *branch analysis*. We do this for a series of discrete values of \bar{n}_r chosen to be integers. The simulation begins in a chosen eigenstate $|i\rangle_0$ of the bare Hamiltonian $\hat{H}_0 \equiv \hat{H}_{s.c.}[\bar{n} = 0]$ (see Eq. 5). Next, we compute the Floquet eigenstates $|m_1\rangle$ of the Hamiltonian $\hat{H}_{s.c.}[\bar{n}_r = 1]$, corresponding to a single photon increase in the readout resonator. We then identify the Floquet eigenstate of this Hamiltonian $|i\rangle_{\bar{n}_r=1}$ that has maximum overlap with $|i\rangle_{\bar{n}_r=0}$. We repeat this process iteratively, increasing \bar{n}_r by one each time:

$$|i_{\bar{n}_r=l}\rangle : \max_m |\langle i_{\bar{n}_r=l-1} | m_{\bar{n}_r=l} \rangle|^2. \quad (7)$$

We thus obtain a set of states $|i\rangle_0, |i\rangle_1, |i\rangle_2, \dots$ that we refer to as a branch. At a heuristic level, this trajectory of states describes the adiabatic evolution of the system as the drive power increases. The drive power in this trajectory increases to emulate a single photon increase in the readout resonator, i.e., $\delta\bar{n}_r = 1$. This corresponds to a constant increase in drive powers (see Eq. 6) $\delta|\xi_{\mu(\phi),r}|^2 = 4g_{\mu(\phi),r}^2$. We make this choice to emulate the more quantum approach to branch analysis captured in Ref. [19, 23]. The probability for this ring-up is studied further for one of the transitions in Sec. III C. We emphasize that our analysis shows the potential impact of PMIST transitions and does not focus on identifying *all* transitions caused by the N parasitic modes in the fluxonium circuit.

We make these choices to observe population changes in the fluxonium potential, i.e., state transitions, as we increase the drive powers. In Eq. 7, the overlaps between Floquet eigenstates are all computed at a fixed time within each drive period (i.e., at times $t_l = 2\pi l/\omega_d$). We have verified that our method yields the same results as Ref. [23] (where a time-averaged overlap was used). Note that the slower or more adiabatic the ring-up of the drive, the more likely it is to observe a state transition. To avoid weak transitions, we increase the drive using discrete steps of $\delta\bar{n}_r = 1$, which corresponds to a linear increase in the drive powers. This choice uses a drive strength increment size $\delta|\xi_{\phi(\mu),r}| = 2g_{\phi(\mu),r}$, different from the driven transmon analysis in Refs. [23] where $\delta|\xi_{\phi,r}| \sim \kappa_r$, the readout resonator’s decay rate. Thus, our simulations can also be used to understand the impact of parasitic state transitions due to a linearly increasing drive on the fluxonium circuit.

For each state $|i_{\bar{n}_r=k}\rangle$ in a given branch, we compute:

1. The expectation value of the fluxo-

Transition No. (see Fig. 3)	Fluxonium MIST Process	Threshold Drive Photon (\bar{n}_r)	Drive Frequency ($\omega_d/2\pi$)	Quasienergy Gap (Δ_{ac})	PMIST	Drive Photons Absorbed (see Fig. 8)
1.	$ \tilde{0}, \tilde{0}\rangle \longleftrightarrow \tilde{13}, \tilde{0}\rangle$	13	8.64 GHz	0.90 MHz	×	3
2.	$ \tilde{0}, \tilde{0}\rangle \longleftrightarrow \tilde{4}, \tilde{2}\rangle^*$	48	8.71 GHz	0.06 MHz	✓	4
3.	$ \tilde{0}, \tilde{0}\rangle \longleftrightarrow \tilde{8}, \tilde{0}\rangle$	~ 0	8.84 GHz	—	×	2
4.	$ \tilde{0}, \tilde{0}\rangle \longleftrightarrow \tilde{6}, \tilde{1}\rangle^*$	46	9.25 GHz	1.63 MHz	✓	2
5.	$ \tilde{0}, \tilde{0}\rangle \longleftrightarrow \tilde{3}, \tilde{1}\rangle$	12	9.36 GHz	0.56 MHz	✓	2
6.	$ \tilde{1}, \tilde{0}\rangle \longleftrightarrow \tilde{17}, \tilde{0}\rangle$	32	8.56 GHz	0.25 MHz	×	4
7.	$ \tilde{1}, \tilde{0}\rangle \longleftrightarrow \tilde{7}, \tilde{0}\rangle$	4	8.73 GHz	0.74 MHz	×	2
8.	$ \tilde{1}, \tilde{0}\rangle \longleftrightarrow \tilde{12}, \tilde{1}\rangle$	19	9.02 GHz	0.12 MHz	✓	4
9.	$ \tilde{1}, \tilde{0}\rangle \longleftrightarrow \tilde{2}, \tilde{1}\rangle$	11	9.05 GHz	0.66 MHz	✓	2
10.	$ \tilde{1}, \tilde{0}\rangle \longleftrightarrow \tilde{14}, \tilde{0}\rangle$	7	9.31 GHz	0.50 MHz	×	3
11.	$ \tilde{1}, \tilde{0}\rangle \longleftrightarrow \tilde{9}, \tilde{0}\rangle$	2	9.41 GHz	1.19 MHz	×	2
12.	$ \tilde{2}, \tilde{0}\rangle \longleftrightarrow \tilde{12}, \tilde{0}\rangle$	3	9.00 GHz	0.73 MHz	×	2
13.	$ \tilde{2}, \tilde{0}\rangle \longleftrightarrow \tilde{0}, \tilde{2}\rangle$	38	9.06 GHz	0.53 MHz	✓	2
14.	$ \tilde{2}, \tilde{0}\rangle \longleftrightarrow \tilde{5}, \tilde{1}\rangle^*$	49	9.41 GHz	2.71 MHz	✓	2

TABLE III. **Measurement-induced-state-transition (MIST) observed in Fig. 3.** Column 1 lists the numbering used to mark the transitions in Fig. 3. Here $|\tilde{i}, \tilde{j}\rangle$ indicates the hybridized eigenstate of H_0 (see Eq. 5) which has the maximum overlap with the state $|i\rangle_\phi \otimes |j\rangle_{\mu=2}$ in the disjoint Hilbert space of qubit mode (ϕ) and parasitic mode ($\mu = 2$). Column 2 lists the MIST processes that start at the lowest average readout photon number \bar{n}_r given by column 3. In some cases, we use $\bar{n}_r \sim 0$ to indicate that the drive frequency is exactly resonant with the transition frequency between the two levels. A ** -marked state indicates hybridization at lower \bar{n}_r due to preceding transitions^a. Column 4 represents the drive frequency $\omega_d/2\pi$ at which these transitions occur. Column 5 yields the quasienergy gap at the avoided crossing labeled as Δ_{ac} . Column 6 indicates if the process cannot occur without the parasitic mode, denoted as PMIST. The various colors for the checkmarks indicate that the PMIST event involves the state $|\tilde{0}, \tilde{0}\rangle$ (red), $|\tilde{1}, \tilde{0}\rangle$ (green) or $|\tilde{2}, \tilde{0}\rangle$ (blue). Column 7 indicates the number of drive photons (#) involved in the energy-conserving process, illustrated in Fig. 8, which is responsible for these transitions.

^a $|\tilde{4}, \tilde{2}\rangle^* : |\tilde{4}, \tilde{2}\rangle \longleftrightarrow |\tilde{14}, \tilde{2}\rangle$ at $\bar{n}_r = 5, \omega_d/2\pi = 8.71$ GHz with $\Delta_{ac} = 4.0$ MHz absorbs 2 drive photons
 $|\tilde{6}, \tilde{1}\rangle^* : |\tilde{6}, \tilde{1}\rangle \longleftrightarrow |\tilde{3}, \tilde{1}\rangle$ at $\bar{n}_r \sim 0, \omega_d/2\pi = 9.25$ GHz
 $|\tilde{5}, \tilde{1}\rangle^* : |\tilde{5}, \tilde{1}\rangle \longleftrightarrow |\tilde{17}, \tilde{0}\rangle$ at $\bar{n}_r = 14, \omega_d/2\pi = 9.41$ GHz with $\Delta_{ac} = 4.2$ MHz absorbs 1 drive photon

fluxonium excitation-number operator $\hat{n}_\phi = \sum_k k |k\rangle_\phi \langle k|_\phi$, where $|k\rangle_\phi$ is the k^{th} bare fluxonium energy eigenstate,

2. The expectation value of the parasitic-mode number operator $\hat{n}_\mu = \hat{a}_\mu^\dagger \hat{a}_\mu$ (for the single mode $\mu = 2$ that we retain), and
3. The quasi-energy of the state $E_i \bmod (\omega_d/2\pi)$.

We can thus identify MIST and PMIST transitions by detecting sudden changes in the number of qubit or parasitic mode excitations as \bar{n}_r increases, indicating an unwanted drive-induced hybridization of eigenstates.

B. Branch analysis PMIST predictions

Fig. 3 illustrates our main result, showing examples of PMIST drive-induced transitions for initial states that have maximum overlap with states $|0\rangle_\phi$, $|1\rangle_\phi$, and $|2\rangle_\phi$ in the fluxonium subspace and the ground state $|0\rangle_{\mu=2}$ in the parasitic subspace. For each branch, we use a color map to plot the average excitation number of the qubit mode $\langle n_\phi \rangle$ (top row) and the parasitic

mode $\langle n_\mu \rangle$, range of readout drive frequencies (horizontal axes), and final readout cavity average photon numbers \bar{n}_r (vertical axes).

Note that both the drive powers, of the qubit $\xi_{\phi r}$ and of the parasitic mode $\xi_{\mu r}$, are exclusively dependent on \bar{n}_r . Thus, we will often interchangeably refer to the drive power as \bar{n}_r . Results are shown for driven frequencies $\omega_d/2\pi$ in the range 8.5 – 9.5 GHz [33]; other regimes are discussed in Sec. IV. For one-dimensional slices of the results at fixed \bar{n}_r , along with the quasi-energies, see App. C3 b.

Any streak or sharp change in color intensity represents a sudden and significant jump in the qubit or parasitic mode population, i.e., MIST or PMIST. The parasitic transitions or PMIST correspond to simultaneous jumps in the population of the modes ϕ (Figs. 3, top row) and $\mu = 2$ (Figs. 3, bottom row), as \bar{n}_r varies. At these points, an avoided crossing in the quasi-energies of the Floquet states confirms the hybridization of the two states involved in the population exchange (see Figs. 21-23 in App. C3 b). Additional resonances may occur at alternate drive frequencies not shown in Fig. 3. Table III lists significant transitions observed in our Floquet simulations and associated processes that cause them, identified

through a perturbative analysis (see App. C3 b) and energy conservation (shown later in Fig. 8). We note that certain MIST processes, including PMIST, involve transitions at the flux sweet spot [34] between parity-conserving states, due to virtual excitations via non-parity-conserving states.

The above results clearly show that coupling to the JJA parasitic modes enables new MIST processes beyond what would be predicted by a fluxonium-only simulation. Further, we find that coupling to parasitic modes can alter and even disrupt transitions that would be predicted by a fluxonium-only calculation. For example, consider transition 14 in Table III. For this drive frequency, if one neglects the qubit-parasitic mode coupling, one finds a MIST transition between $|\tilde{2}, \tilde{0}\rangle \leftrightarrow |\tilde{17}, \tilde{0}\rangle$ via the absorption of three drive photons. Including the parasitic mode, the nature of this process changes. As drive power (i.e., \bar{n}_r) increases, one first finds a transition between the states $|\tilde{5}, \tilde{1}\rangle \leftrightarrow |\tilde{17}, \tilde{0}\rangle$ at a threshold drive photon number of $\bar{n}_r = 14$. As the drive power further increases, one obtains a transition $|\tilde{2}, \tilde{0}\rangle \leftrightarrow |\tilde{5}, \tilde{1}\rangle$ at $\bar{n}_r = 41$, enabled by the earlier hybridization of $|\tilde{5}, \tilde{1}\rangle$ and $|\tilde{17}, \tilde{0}\rangle$.

Another qualitatively new feature that arises due to the parasitic modes is the possibility of MIST-like transitions where the qubit loses excitations. For example, consider transition 12 in Table III. In this process, two drive photons are absorbed, the fluxonium state has a downward transition $|2\rangle_\phi \rightarrow |0\rangle_\phi$, and the net energy released is used to excite the parasitic mode $|0\rangle_\mu \rightarrow |2\rangle_\mu$. By simple energy conservation, such an effect is not possible without a parasitic mode. This transition can even modify the T_1 lifetime of the $0 - 2$ fluxonium subspace, and not just contribute to leakage like general MIST phenomena.

Our results also display branch bunchings (see Figs. 21, sub-panels (2) and (4), in App. C3 b for reference) instead of crossings in the negative detuning regime. This is contrary to Ref. [23] where such branch bunching has been observed only in the positive detuning ($\omega_q > \omega_r$) regime. Consider for example transitions 3 and 4 in Table III. Here, we are driving at a frequency that exactly matches the transition frequency between two non-computational states, such that these states immediately start to hybridize into an equal superposition of the two original undriven states. For example, in transition 4, the readout drive frequency exactly matches the $|3\rangle_\phi \rightarrow |6\rangle_\phi$ transition frequency at zero readout excitations. In this case, levels $|3\rangle_\phi$ and $|6\rangle_\phi$ hybridize for any non-zero drive power \bar{n}_r (see Fig. 21 in App. C3 b). While this effect is not limited to PMIST, we highlight that the presence of parasitic modes can result in more exotic transitions. For example, in transition 4, one such transition between the states $|\tilde{3}, \tilde{1}\rangle$ and $|\tilde{6}, \tilde{1}\rangle$, where the parasitic mode was excited, eventually lead to a PMIST effect involving the computational state $|\tilde{0}, \tilde{0}\rangle$. See Fig. 21, sub-panel (4), for explicit population and quasienergy plots involving the three states.

Our findings reveal that for our specific circuit choice, JJA parasitic modes can become significantly populated, as we show in Fig. 3. Having identified key

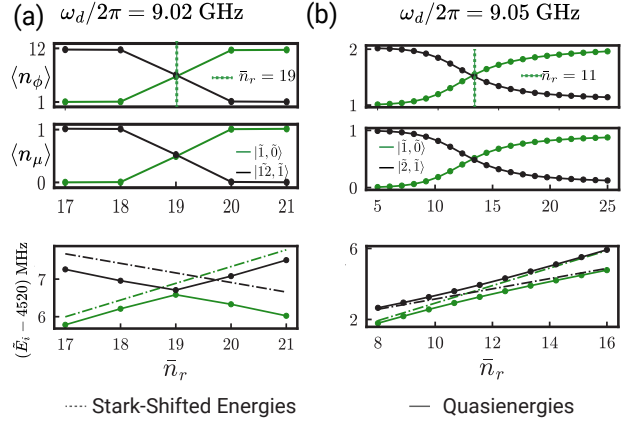


FIG. 4. **PMIST processes including state $|\tilde{1}, \tilde{0}\rangle$.** Examples of PMIST using transitions (a) 8 and (b) 9 from Table III involving the $|\tilde{1}, \tilde{0}\rangle$ state, with maximum overlap to the un-hybridized state $|1\rangle_\phi \otimes |0\rangle_{\mu=2}$. **Top row:** Qubit mode average occupation $\langle n_\phi \rangle$. **Middle row:** Parasitic mode average occupation $\langle n_\mu \rangle$. **Bottom row:** $\tilde{E}_i = E_i \bmod \omega_d$ where E_i is the Stark-shifted eigen-energy (dashed) obtained from first-order perturbative calculations, or quasi-energy (solid) obtained from Floquet simulations showing avoided crossings. Plots are extracted from numerical data used in Fig. 3. The data points are connected by lines for visual aid.

transitions that cause these effects, we now calculate the transition rates in detail and the consequences on qubit coherence.

For further insights, we now examine how the quasienergies and excitation numbers change as a function of drive power \bar{n}_r when we pass through an avoided crossing associated with a PMIST process. Figs. 4(a,b) show how average qubit and parasitic mode excitation numbers change as a function of drive power $f(\bar{n}_r)$ for fixed drive frequency corresponding to 8, 9 (respectively) in Table III. Both these transitions involve starting in the qubit's first excited state (i.e., branches associated with the undriven state $|\tilde{1}, \tilde{0}\rangle$). The simultaneous exchange of population in the qubit mode ϕ , shown in the top panels, and the parasitic mode $\mu = 2$, shown in the middle panels, confirms that the transitions are indeed PMIST.

The bottom panel of Fig. 4 shows the corresponding behavior of the branch quasi-energies as a function of drive power, for the same drive parameters. We plot both quasi-energies from the Floquet calculations and the predictions of a perturbative calculation including drive-induced Stark shifts (see App. C3 a for details). For Fig. 4, the perturbative calculations predict the onset of an avoided crossing at a drive power close to the value derived from the Floquet simulations. Note that these transitions occur at relatively modest average readout cavity photon numbers $\bar{n}_r = 11, 19$.

C. Transition probability

Our Floquet branch analysis gives strong evidence that MIST and PMIST transitions may occur during the ring-up of the resonant during a readout pulse.

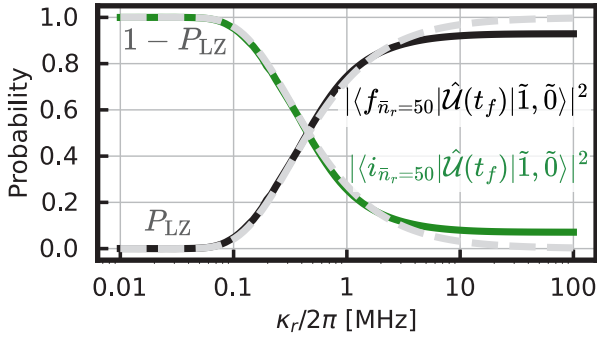


FIG. 5. **PMIST transition probabilities as a function of readout cavity ring-up rate.** We plot the probabilities for adiabatic (green) and diabatic (black) transitions for a time-dependent ring-up of the average cavity photon number from $\bar{n}_r = 0$ to $\bar{n}_r = 50$, for different choices of the cavity damping rate κ_r , which controls the speed of the sweep (see text). We start the system in the qubit's first excited state $|\tilde{1}, \tilde{0}\rangle$. The drive frequency is $\omega_d/2\pi = 9.05$ GHz, corresponding to the crossing shown in Fig. 4(b). Here, $|f_{\bar{n}_r=50}\rangle$ and $|i_{\bar{n}_r=50}\rangle$ are the final states in the end of branch analyses for $|\tilde{2}, \tilde{1}\rangle$ and $|\tilde{1}, \tilde{0}\rangle$, respectively. The time-evolution operator is denoted by $\hat{U}(t_f) = \mathcal{T} \exp(-i \int_0^{t_f} \hat{H}_{s.c.}(t) dt)$, where \mathcal{T} indicates time-ordering and $t_f = 10/\kappa_r$. The adiabatic (green) curve corresponds to an unwanted PMIST transition. We also plot the predictions of the Floquet branch analysis combined with a Landau Zener approximation for the probabilities (gray), which are in excellent agreement over a wide range of κ_r .

Here, we validate this approach by focusing on a specific transition, and we show (via explicit time-dependent simulations) that it occurs as predicted. We also show that this full-time-domain simulation is in agreement with a Landau-Zener analysis that takes as inputs the result of the Floquet branch analysis.

We focus on the PMIST transition shown in Fig. 4(b), which corresponds to an avoided crossing energy gap of $\Delta_{ac} = 0.66$ MHz. We perform a full time-dependent simulation of $\hat{H}_{s.c.}$ in Eq. 4, using time-dependent drive powers determined by the time-dependent average readout cavity photon number in the form:

$$\bar{n}_r(t) = \bar{n}_r(1 - e^{-\kappa_r t/2})^2. \quad (8)$$

This corresponds to the ring-up of a resonantly driven cavity with a damping rate κ_r [21–23].

To calculate transition probabilities in this full time-dependent simulation, we initiate the system in the dressed state $|\tilde{1}, \tilde{0}\rangle$, evolve under $\hat{H}_{s.c.}(t)$ from $t = 0$ to $t = 10/\kappa_r$, and then compute the overlap of this state with the Floquet branches of the two states $|i\rangle = |\tilde{1}, \tilde{0}\rangle$ and $|f\rangle = |\tilde{2}, \tilde{1}\rangle$ associated with our predicted transition. We then repeat this calculation for different choices of κ_r , examining how the transition probabilities vary, with the results shown in Fig. 5. As expected, the probability of remaining adiabatic (green curve) decreases as one increases κ_r . Note that at large κ_r , adiabatic evolution corresponds to a detrimental PMIST transition, as the most likely final state $|\tilde{2}, \tilde{1}\rangle$ has an extra qubit and parasitic mode excitation compared to the initial state $|\tilde{1}, \tilde{0}\rangle$.

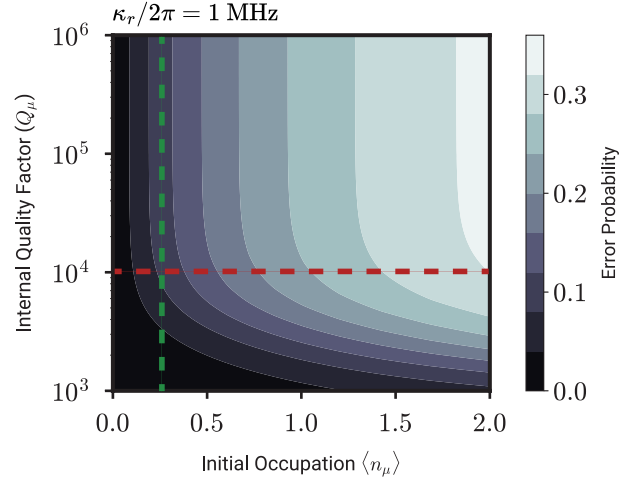


FIG. 6. **Dephasing error probability due to random decay of an excited parasitic mode, after PMIST, various internal parasitic quality factors.** The horizontal red line shows the quality factor quoted in [13]. The green line shows the dephasing error probability for transition 9 for various quality factors at $\kappa_r/2\pi = 1$ MHz (see Figs. 4(b) and 5).

For small κ , the above probabilities are in agreement with the predictions of our Floquet branch analysis combined with a Landau-Zener approximation to the probability of a non-adiabatic transition [23, 31] (see App. C3 c). These probabilities (P_{LZ}) are shown in gray in Fig. 5. We see agreement for most of the values of κ_r between the time-domain simulations and our Landau-Zener calculations using the Floquet quasienergies. For large κ_r , we find that the probabilities do not saturate to 1 and 0 as would be expected in the standard Landau-Zener problem; they do, however, sum to unity (hence transitions to additional levels are not contributing). We attribute this small deviation to dressing effects that go beyond the simple two-level Landau-Zener paradigm.

D. Post-readout qubit dephasing

The new PMIST processes we identify here can also potentially create errors *after* the readout pulse is complete, as they lead to a new dephasing channel. A PMIST process results in a JJA parasitic mode having a residual excitation post-readout. As there is a non-zero dispersive coupling $\chi_{\mu\phi}$ between these modes and the qubit, and as these modes are believed to have relatively large internal quality factors $Q \sim 10^4$ [13, 35], this will lead to the qubit acquiring a random phase (tied to the random time at which the parasitic mode relaxes). Below, we show master equation simulation results which quantify the scale of phase errors that would result from such processes.

For concreteness, we consider a readout pulse with a frequency corresponding to the PMIST transition labeled 9 in Fig. 4(b) and a cavity damping rate $\kappa_r/2\pi = 1$ MHz (which determines the ring-up time of the cavity to the maximum drive powers given by $\bar{n}_r = 50$). For these parameters, our previous simula-

tions and Landau-Zener analysis suggest that at the end of the readout pulse, the parasitic mode will have an average non-zero excitation $\langle n_\mu \rangle = 0.25$. In fact, for many transitions, this population can be as high as $\langle n_\mu \rangle = 2.0$ as shown in Table III. We now analyze how the decay of such a population dephases the fluxonium (assuming it is prepared after readout in the state $|+\rangle = \frac{|0\rangle_\phi + |1\rangle_\phi}{\sqrt{2}}$). Our explicit time-dependent simulations shown in Fig. 4 indicate that using a realistic readout power, the final post-readout parasitic mode population is sufficient to introduce phase errors of about 0.1.

A master equation simulation illustrates the resulting qubit dephasing due to this mechanism. We investigate a reduced system of the parasitic mode $\mu = 2$ and the fluxonium qubit (modeled as a two-level system), interacting under the dispersive Hamiltonian $\hat{H}_\theta/\hbar = \chi_{\phi\mu} \hat{a}_\mu^\dagger \hat{a}_\mu \sigma_z$, and with a loss dissipator having collapse operator $\sqrt{\kappa_\mu} \hat{a}_\mu$, describing the parasitic mode internal loss. We start the system in a product state, where the parasitic mode has some initial non-zero occupation, and the qubit is in the pure state $|+\rangle$. We let the system evolve for a time $T_f = 10/\kappa_\mu$ long enough to allow the parasitic mode to relax, and then compute the fidelity of the final qubit state with the initial state $|+\rangle$, defining the error probability to be the corresponding infidelity. This quantity is plotted in Fig. 6, both as a function of the initial parasitic mode occupancy $\langle n_\mu \rangle$ and its internal quality factor Q_μ . We present an illustrative calculation where we initialize the parasitic mode in a thermal state with an average occupation number equal to $n_\mu \in [0, 2]$. We find that for an internal quality factor Q_μ of 10^4 , an initial population of $\langle n_\mu \rangle = 0.25$ in the parasitic mode introduces a dephasing error probability $\epsilon \sim 0.1$, indicating that PMIST may limit qubit coherence if the circuit is not designed with care[36].

IV. EFFECTS OF CIRCUIT MODIFICATIONS ON PMIST

Having identified PMIST as a potentially significant qubit error channel, we now turn to mitigation strategies. Here, we discuss how adjusting the qubit frequency, readout resonator frequency and parasitic mode frequencies may affect the unwanted transitions. We rely on derivations in Ref. [26] for the circuit in Fig. 2 (see App. A for the Lagrangian).

A. Root causes of PMIST

We identify the primary causes of PMIST:

- High coupling strength $g_{\phi\mu}$ by analyzing the effect of setting different coupling strengths to zero in Floquet simulations.
- Low frequency gap $\omega_r - \omega_{\mu=2}$ by enumerating MIST processes using energy conservation and verifying predictions against Table III.

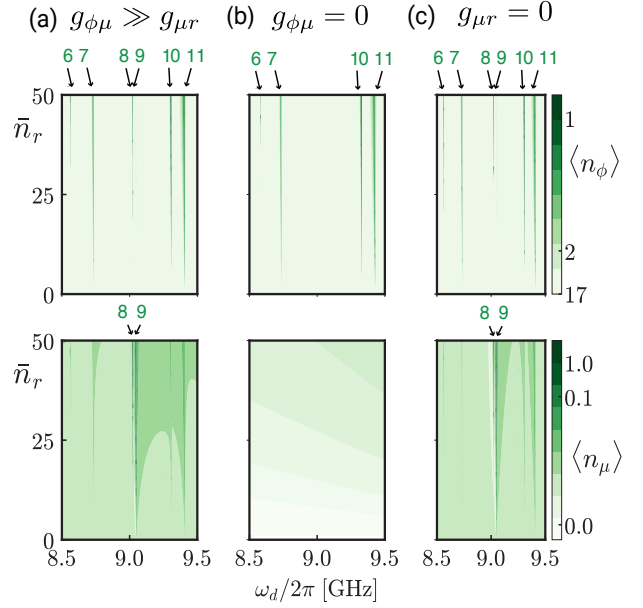


FIG. 7. **Sensitivity of PMIST processes to parasitic mode coupling strengths.** Panels show the result of Floquet branch analyses for the circuit parameters in Table I. MIST processes observed in Fig. 3 are labeled with numbers and indicated with arrows. (a) All parameters are the same as in Fig. 3(b). (b) Same, except now we set the parasitic mode to qubit coupling $g_{\phi\mu}$ to zero. Note that all PMIST features are now gone. (c) Same as (a), but we now set the parasitic mode to readout resonator coupling $g_{\mu r}$ to zero. As with previous Floquet branch analysis plots, color scales use a log scale to make transitions more visible.

First, we compare the results of Floquet branch analyses for the initial state $|\tilde{1}, 0\rangle$ under different coupling conditions, drive frequencies, and amplitudes. Fig. 7 identifies the main mechanism causing PMIST as the fluxonium-parasitic-mode coupling, $g_{\phi\mu}$. Fig. 7(a) reproduces the Floquet simulation results from Fig. 3. Using our previous choice of coupling strengths $g_{\phi\mu}$ and $g_{\mu r}$, PMIST are shown as transitions 8 and 9 around $\omega_d/2\pi \sim 9$ GHz. In contrast, Fig. 7(b) shows results from the same simulation, but with $g_{\phi\mu}$ set to zero. PMIST is absent, evident from the lack of parasitic transitions (8, 9) in the top panel and no streak or sharp change in color indicating parasitic mode excitations in the bottom panel. For $g_{\phi\mu} = 0$, the parasitic mode population always remains below $\langle n_\mu \rangle = 10^{-4}$. Therefore, we conclude that a finite $g_{\phi\mu}$ is the main mechanism behind PMIST: the readout resonator exchanges multiple excitations simultaneously with the parasitic mode and qubit, facilitated by the parasitic mode-qubit coupling $g_{\phi\mu}$. Further, Fig. 7(c) shows that setting the parasitic-readout coupling to zero does not reduce PMIST. Thus, the qubit-readout coupling $g_{\phi r}$ alone does not cause significant transitions or PMIST processes without $g_{\phi\mu}$.

Consequently, we turn to reducing the coupling strength $g_{\phi\mu}$ as the first strategy for reducing the likelihood of PMIST processes.

Next, we plot energy-conserving processes in Fig. 8

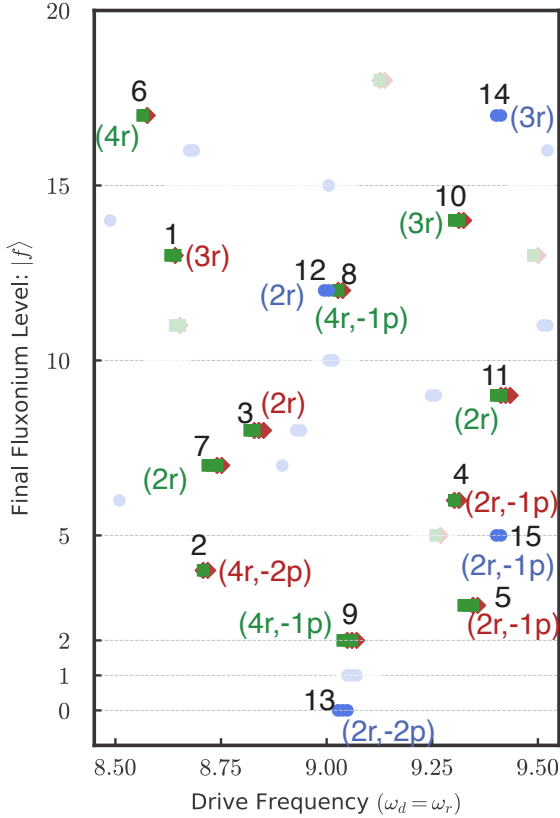


FIG. 8. **Energy-conserving processes** $|\tilde{i}, \tilde{0}\rangle \leftrightarrow |\tilde{f}, \tilde{y}\rangle$ for Eq. 9 with $x \leq 4, y \leq 2, f \leq 20$ and $i = 0$ (red diamonds), $i = 1$ (green squares), $i = 2$ (blue circles). The horizontal lines indicate the initial state i for visual aid. Labels in black correspond to transition # listed in Table III. The colored labels correspond to the disjoint subspaces for simplified representation, but the energy conservation uses the eigenenergies of the hybridized eigenstates of H_0 (see Eq. 5). For example, the green label (4r, -1p), for transition 8 of Table III, shows the number of readout photons absorbed (4) and the number of parasitic mode ($\mu = 2$) photons emitted (1) in the process. The faded points are weaker transitions not captured in the Floquet simulations.

that involve the parasitic mode $\mu = 2$ to understand the spectrum of resonance conditions. We plot all processes that are approximately energy-conserving within a window ϵ , i.e., that satisfy:

$$\left| |x\omega_r - \tilde{\Delta}_{if,y}/\hbar| = |x\omega_r - y\omega_\mu - \Delta_{if}/\hbar| \right| \leq \epsilon, \quad (9)$$

where $\tilde{\Delta}_{if,y}$ is the transition energy between levels $|\tilde{i}, \tilde{m}\rangle$ and $|\tilde{f}, \tilde{n}\rangle$ such that $|m - n| = y$ [37]. We assume a liberal value of $\epsilon = 25$ MHz to identify processes that could become resonant once Stark shifts (which are of order ~ 25 MHz) due to the readout drive are accounted for (see App. C 3 a for details). Fig. 8 depicts all multi-photon processes that occur with approximate energy conservation, for $x \leq 4$, for drive frequencies within our target range, and when starting in one of the three lowest fluxonium levels[38]. The parenthesized labels in color denote the number of readout photons (xr) and parasitic mode photons (yp) required for the transition in the fluxonium subspace,

where a positive (xr) index denotes readout photon absorption while a negative (yp) index denotes parasitic mode excitation[39]. Many of the transitions in Fig. 8 have large transition numbers, requiring e.g. four readout photons to be absorbed for a PMIST excitation. Several readout photons are required to bridge a large energy gap between the readout frequency and parasitic mode frequency. In the perturbative regime, the larger the photon number in a transition, the lower its transition rate. Therefore, as this gap increases, the likelihood of PMIST processes decreases.

Thus, as the second strategy towards reducing PMIST, we discuss the effect of increasing the frequency gap between the readout mode and the lowest-frequency parasitic mode ($\omega_r - \omega_{\mu=2}$).

B. Reducing the coupling strength $g_{\phi\mu}$

Here, we analyze the dependence of these coupling strengths on circuit and readout parameters. As discussed, only even-index parasitic modes have a non-zero coupling to the qubit (see the Lagrangian in App. A). The coupling strength $g_{\phi\mu}$ between an even parasitic mode and the qubit is given by

$$\frac{g_{\phi\mu}}{2\pi} = \frac{4}{\sqrt{2N}} \frac{\tilde{E}_c^\phi \tilde{E}_{c,\mu}^e c_\mu}{E_{C_{g,j}} s_\mu^2} \cdot N_{\phi\text{ZPF}} \cdot N_{\mu\text{ZPF}}, \quad (10)$$

where $c_\mu = \cos \frac{\pi\mu}{2N}$, $s_\mu = \sin \frac{\pi\mu}{2N}$. \tilde{E}_c^ϕ and $\tilde{E}_{c,\mu}^e$ are the qubit and even parasitic mode charging energies, respectively, and $N_{\phi/\mu,\text{ZPF}}$ are the zero-point fluctuation values for the qubit and parasitic modes. \tilde{E}_c^ϕ and $N_{\phi/\mu,\text{ZPF}}$ are given in Apps. B 1, and

$$E_{c,\mu}^e = \left[\frac{1}{E_{C_j}} + \frac{1}{4E_{C_{g,j}} s_\mu^2} \right]^{-1}. \quad (11)$$

All the other variables represent independent quantities listed in Table I.

We see that suppressing the parasitic capacitance to ground near the junction array suppresses the qubit-parasitic coupling $g_{\phi\mu}$. However, this is constrained by practical limitations to order $\mathcal{O}(0.1)$ fF per junction. The parasitic modes with the strongest coupling to the qubit have $\mu \ll N$. The large N , small μ limit with $c_\mu \approx 1$ yields

$$\tilde{E}_{c,\mu}^e \approx 4E_{C_{g,j}} s_\mu^2, \quad \tilde{E}_c^\phi \propto \frac{1}{N^2} \implies g_{\phi\mu} \propto \frac{1}{N^{5/2}}. \quad (12)$$

These dependencies are plotted in Fig. 12 of App. B 1. We find that the coupling strength *decreases* with the number of junctions N ; however, a limit to this increase may be set by the requirement of a constant inductance $E_L = E_{J_j}/N$ (see App. B 1).

C. Increasing the readout and parasitic frequency gap

We discuss tailoring the circuit to avoid resonance conditions required for PMIST.

a. Lowest parasitic-mode frequency $\omega_{\mu=2}$: To mitigate PMIST, adjust ω_{μ} so that $\omega_{\mu} \gg \omega_r$ for $\mu = 2$, requiring more readout photons for PMIST and reducing transition rates. The parasitic mode frequencies for even μ are:

$$\frac{\omega_e}{2\pi} = \sqrt{8E_{c,\mu}^e E_{J_j}} \quad (13)$$

See Eq. 11 for $E_{c,\mu}^e$ and Table I for E_{J_j} . In the large N and small μ limit, parasitic frequency decreases with increased junction count and parasitic ground capacitance. Decreasing parasitic ground capacitance reduces both parasitic frequency and qubit-parasitic coupling. Increasing N reduces the coupling strength but decreases the gap between ω_d and ω_{μ} . Decreasing N to increase this gap requires considering nonlinear corrections [26] and fixed inductance, making the analysis complex.

b. Drive frequency (ω_d): Reducing the readout resonator frequency increases the gap between readout and parasitic mode excitations, requiring more readout photons for PMIST and lowering transition rates. However, Floquet simulations in the low-frequency readout regime (Fig. 9) show higher parasitic mode populations compared to Fig. 3. This is due to increased resonance density when $\omega_d/2\pi \approx 6$ GHz, matching the plasmon transition $\omega_{12}/2\pi$ of the fluxonium qubit mode and half the parasitic mode frequency. Reduced readout frequencies introduce multiple frequency collisions, increasing PMIST resonances. Formal transition probability calculations (Sec. III C) are needed to predict the impact of these additional resonances. Energy conservation indicates that despite more PMIST effects, such transitions will be higher-order processes (large x_r) and thus suppressed for typical readout powers where $\bar{n}_r \sim \mathcal{O}(10^2)$ [16].

V. CONCLUSION AND FURTHER WORK

In this work, we have analyzed the impact of internal array degrees of freedom on driven JJA fluxonium qubits, showing that new pathways for measurement-induced state transitions can occur via excitations of JJA parasitic modes. These processes, which we have called PMIST, occur at particular resonance conditions when the energy of several readout photons is equal to a small number of parasitic mode excitations and a fluxonium mode excitation.

We find that PMIST transitions can occur at meaningfully high rates (with avoided crossing quasi-energy gap $\Delta_{ac} = 0.66$ MHz) because of the strong coupling between parasitic modes and the qubit. As a result, such state transitions can occur even at low readout drive powers (corresponding to small intracavity photon numbers) while using typical parameters that enable high-fidelity, dispersive readout. For example, we have shown that PMIST does lower the onset of MIST processes to ~ 10 readout photons at certain drive frequencies. In addition, PMIST has the potential to significantly dephase the qubit post-measurement. This could in turn limit the qubit gate fidelities required for quantum error correction and ultimately the performance of a quantum processor. **However, despite**

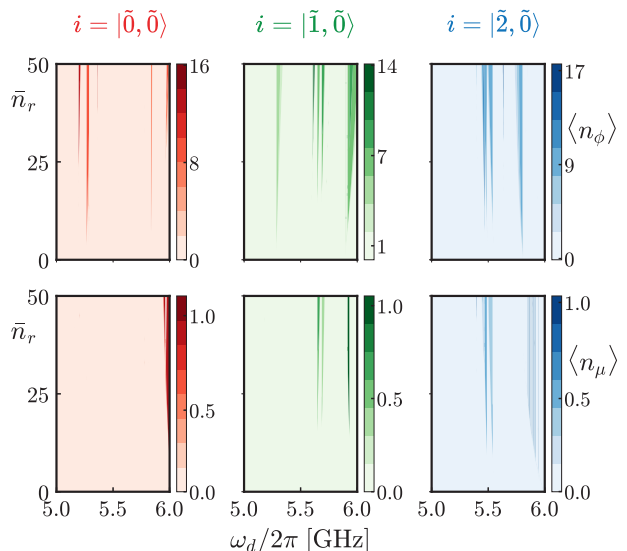


FIG. 9. **Floquet simulations at lower readout frequencies.** Circuit parameters are the same as in Tables I and II for branch analysis starting in the dressed hybridized eigenstate $i = |\vec{k}, \vec{0}\rangle$, with maximum overlap to the un-hybridized states $|k\rangle_{\phi} \otimes |0\rangle_{\mu=2}$. The figures are plotted in linear scale, unlike Fig. 3, making any streaks due to significantly weaker transitions unnoticeable.

the strong parasitic mode and qubit coupling, we find that PMIST is unlikely to occur for the vast majority of readout resonator frequencies. Therefore, these processes can be avoided via a judicious choice of readout, junction array, and fluxonium parameters. We analyze the trend in PMIST for various drive frequencies, parasitic mode frequencies, coupling constants, and circuits with two different qubit frequencies equal to ~ 30 and ~ 300 MHz.

We have presented a first analysis toward understanding the role of parasitic modes in the dispersive readout dynamics of a fluxonium circuit. Mitigating the parasitic mode excitations could involve careful selection of the readout resonator frequency and varying junction energies along the array to localize parasitic modes. Such modifications alter the parasitic mode spectrum towards reducing excitation probability. The circuit parameters used in this work correspond to a parasitic mode of the fluxonium's junction array. However, other modes with similar frequencies may also participate in the environment of the fluxonium. This may include, for example, confined package modes, slot line modes, and harmonics of coplanar waveguide resonators for readout. Our results show the significance of considering all such modes when driving many excitations into highly nonlinear circuits.

VI. ACKNOWLEDGMENTS

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for supporting the quantum computing program.

Appendix A: Role of symmetry in readout circuits

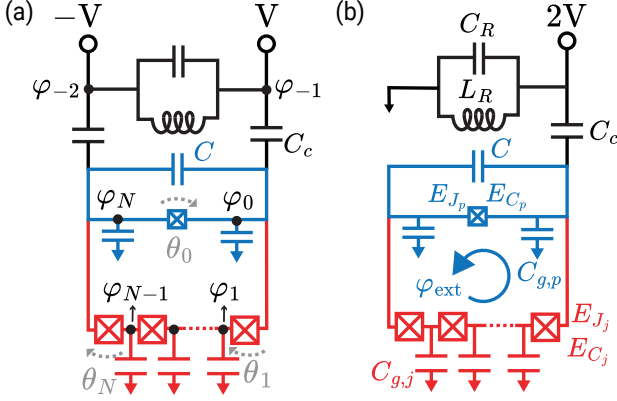


FIG. 10. **Alternative readout circuits.** (a) Symmetric circuit same as Fig. 2(a), (b) Asymmetric circuit inspired by Ref. [5]. Alternative (b) requires a single-point connection to the readout line, unlike the symmetric circuit in (a). The symmetric circuit is used as a reference for denoting phase variables φ_i at each node and phase difference variables θ_j across each junction, used in the derivation of the Lagrangian for both circuits.

Parameters	Variables	Values
Phase-slip junction capacitance	C_p	3.17 fF
Differential capacitance	C	11.27 fF
JJA junction capacitance	C_j	26.2 fF
Phase-slip ground capacitance	$C_{g,p}$	10 fF
JJA ground capacitance	$C_{g,j}$	0.1 fF
Coupling capacitance	C_c	1 fF
ZPF of fluxonium charge operator	$N_{\phi, \text{ZPF}}$	0.36
ZPF of parasitic charge operator	$N_{\mu=2, \text{ZPF}}$	1.58

TABLE IV. **Capacitances and zero-point fluctuation (ZPF) values.** These capacitance values for the symmetric circuits are used throughout this article except App. D. For capacitive, inductive, and Josephson energy values, see Table I.

The fluxonium readout circuit in Fig. 2 can be modified in several ways, affecting performance metrics. This circuit has a configuration with symmetry (identified in Ref. [29]) that removes coupling to the lowest frequency mode $\mu = 1$ [26]. Crucial to this symmetry are the equal coupling capacitances on both ends of the circuit (see Fig. 10(a)). We present a modification with a different grounding option that does not respect this symmetry (see Fig. 10(b)). This asymmetric circuit, inspired by [5], is relevant for a hangar geometry with a single readout feedline. In this appendix, we derive the Lagrangian for both circuits and

show that not preserving this symmetry can be detrimental to readout. Therefore, we use the symmetric circuit for fluxonium readout analyses in the rest of the appendix and the main text.

1. Lagrangian

To derive the Lagrangians, we follow the recipe in Refs. [26, 29] for the symmetric circuit and adapt it for the asymmetric circuit in Fig. 10(b). Importantly, we show that the symmetry in the circuit 10(a), which prevents any coupling with the lowest-frequency parasitic mode ($\mu = 1$), is not preserved in this circuit. The presence of coupling to this mode is detrimental to readout because of the low-frequency gap between the readout and the parasitic mode, as discussed in Sec. IV.

The Lagrangian corresponding to both circuits is a combination of the Lagrangians, $\mathcal{L}_{\text{phase-slip}}$ from the phase-slip junction shown in blue (comprising of the junction with $E_J/E_C \sim 1$ and the differential capacitor C), \mathcal{L}_{JJA} from the (red) junctions in the array, \mathcal{L}_g from the ground capacitances, \mathcal{L}_R from the readout resonator and \mathcal{L}_c due to the coupling capacitances C_c . The node flux variables at various points in the circuit are denoted by $\varphi_i = 2\pi\Phi_i/\Phi_0$. We mark the phase difference across the junctions in the array, $\theta_i = \varphi_i - \varphi_{i-1}$, and across the phase-slip junction, $\theta_0 = \varphi_N - \varphi_0$, in Fig. 10(a). Similarly, the voltage drop across each junction is given by the phase evolution equation $\theta_i = \dot{\varphi}_i - \dot{\varphi}_{i-1} = 2\pi V_i/\Phi_0$ where $\Phi_0 = h/2e$ the superconducting flux quantum. We will use subscripts j, p for JJA and the phase-slip junction coordinates, respectively. For the Lagrangian of the symmetric circuit [26, 29] (setting $\hbar = 1$), we have,

$$\mathcal{L} = \mathcal{L}_{\text{phase-slip}} + \mathcal{L}_{\text{JJA}} + \mathcal{L}_g + \mathcal{L}_R + \mathcal{L}_c, \quad (\text{A1})$$

where

$$\mathcal{L}_{\text{phase-slip}} = \frac{1}{16E_C}(\dot{\varphi}_N - \dot{\varphi}_0)^2 - E_{J_p} \cos\left(\sum_{i=1}^N \theta_i + \varphi_{\text{ext}}\right) \quad (\text{A2})$$

$$\mathcal{L}_{\text{JJA}} = \sum_{i=1}^N \frac{1}{16E_{C_j}}(\dot{\varphi}_i - \dot{\varphi}_{i-1})^2 - E_{J_j} \cos(\theta_i) \quad (\text{A3})$$

$$\mathcal{L}_R = \frac{1}{16E_{C_R}}(\dot{\varphi}_{-1} - \dot{\varphi}_{-2})^2 + \frac{1}{16E_{L_R}}(\varphi_{-1} - \varphi_{-2})^2 \quad (\text{A4})$$

$$\mathcal{L}_g = \sum_{i=1}^{N-1} \frac{\dot{\varphi}_i^2}{16E_{C_{g,j}}} + \sum_{i=0,N} \frac{\dot{\varphi}_i^2}{16E_{C_{g,p}}} \quad (\text{A5})$$

$$\begin{aligned} \mathcal{L}_c &= \frac{1}{16E_{C_c}}(\dot{\varphi}_{-1} - \dot{\varphi}_0)^2 + \frac{1}{16E_{C_c}}(\dot{\varphi}_{-2} - \dot{\varphi}_N)^2 \\ &= \frac{\dot{\varphi}_0^2}{16E_{C_c}} + \frac{\dot{\varphi}_{-1}^2}{16E_{C_c}} - \frac{\dot{\varphi}_0 \dot{\varphi}_{-1}}{8E_{C_c}} \\ &\quad + \frac{\dot{\varphi}_N^2}{16E_{C_c}} + \frac{\dot{\varphi}_{-2}^2}{16E_{C_c}} - \frac{\dot{\varphi}_N \dot{\varphi}_{-2}}{8E_{C_c}}. \end{aligned} \quad (\text{A6})$$

The definitions and values of capacitive energies used here are given in Table I for the symmetric circuit.

The terms associated with $\dot{\varphi}_i(\theta_i)$ are the kinetic (potential) energy terms. We can ignore the harmonic oscillator Lagrangian \mathcal{L}_R due to triviality. Note that for the asymmetric circuit in Fig. 10(b), we can impose $\dot{\varphi}_{-2} = 0$ and $C_c = 0$ on one end of the circuit. First, we expand on the derivation for the symmetric case in Refs. [26, 29] for completeness and then impose these conditions to derive the Lagrangians for the asymmetric case.

We use the definition of phase difference quadratures and the fluxoid quantization,

$$\sum_{l=1}^m \theta_l = \varphi_m - \varphi_0 \quad (\text{A7})$$

$$\sum_{m=0}^N \theta_m + \varphi_{\text{ext}} = 2\pi z, \quad z \in \mathbb{Z}, \quad (\text{A8})$$

with an external flux choice of $\varphi_{\text{ext}} = \pi$ as per the main text. Writing the the Lagrangian in this new basis follows $\partial\mathcal{L}/\partial\dot{\varphi}_0 = 0$, yielding the expression,

$$\begin{aligned} \dot{\varphi}_0 = E_t & \left(\frac{\dot{\varphi}_{-1}}{E_{C_c}} + \frac{\dot{\varphi}_{-2}}{E_{C_c}} - \sum_{l=1}^N \frac{\dot{\theta}_l}{E_{C_c}} - \sum_{l=1}^N \frac{\dot{\theta}_l}{E_{C_{g,p}}} \right. \\ & \left. - \sum_{i=1}^{N-1} (N-i) \frac{\dot{\theta}_i}{E_{C_{g,j}}} \right) \end{aligned} \quad (\text{A9})$$

where

$$E_t = \left(\frac{2}{E_{C_c}} + \frac{N-1}{E_{C_{g,j}}} + \frac{2}{E_{C_{g,p}}} \right)^{-1} \quad (\text{A10})$$

is the total capacitive energy of the circuit due to the parasitic ground capacitances and coupling capacitances. Using the expression for $\dot{\varphi}_0$, we get $\mathcal{L}_c + \mathcal{L}_g =$,

$$\begin{aligned} & \frac{(\dot{\varphi}_{-1}^2 + \dot{\varphi}_{-2}^2)}{16E_{C_c}} \left(1 - \frac{E_t}{E_{C_c}} \right) + \frac{\dot{\varphi}_{-1}\dot{\varphi}_{-2}}{8E_{C_c}} \left(\frac{E_t}{E_{C_c}} \right) \\ & + \sum_{i=1}^N \left(\frac{\dot{\varphi}_{-1}\dot{\theta}_i}{E_{C_c}} + \frac{\dot{\varphi}_{-2}\dot{\theta}_i}{E_{C_c}} \right) \left(\frac{E_t}{8E_{C_c}} + \frac{E_t}{8E_{C_{g,p}}} \right) \\ & + \sum_{i=1}^{N-1} \left(\frac{\dot{\varphi}_{-1}\dot{\theta}_i}{E_{C_c}} + \frac{\dot{\varphi}_{-2}\dot{\theta}_i}{E_{C_c}} \right) \frac{(N-i)E_t}{8E_{C_{g,j}}} \\ & - \sum_{i=1}^N \frac{\dot{\varphi}_{-2}\dot{\theta}_i}{8E_{C_c}} + \left(\sum_{i=1}^N \dot{\theta}_i \right)^2 \left(\frac{1}{16E_{C_c}} + \frac{1}{16E_{C_{g,p}}} \right) \\ & \times \left(1 - \frac{E_t}{E_{C_c}} - \frac{E_t}{E_{C_{g,p}}} \right) + \frac{\sum_{i=1}^{N-1} (\sum_{l=1}^i \dot{\theta}_l)^2}{16E_{C_{g,j}}} \\ & - 2 \sum_{l=1}^N \sum_{l'=1}^{N-1} \dot{\theta}_l \dot{\theta}_{l'} (N-l') \left(\frac{E_t}{8E_{C_c}E_{C_{g,j}}} + \frac{E_t}{8E_{C_{g,p}}E_{C_{g,j}}} \right) \\ & - \frac{E_t}{16} \left[\frac{\sum_{i=1}^{N-1} (N-i)\dot{\theta}_i}{E_{C_{g,j}}} \right]^2. \end{aligned} \quad (\text{A11})$$

We will eventually use the scalar voltage values for $\dot{\varphi}_{-1}, \dot{\varphi}_{-2}$, and hence we can ignore any term solely dependent on these variables. The terms independent of $\dot{\varphi}_{-1}, \dot{\varphi}_{-2}$ are combined as $\sum_{l=1}^N \sum_{l'=1}^N \mathcal{G}_{ll'} \dot{\theta}_l \dot{\theta}_{l'}$ where,

$$\mathcal{G}_{ll'} = \left[\frac{N - \max\{l, l'\}}{16E_{C_{g,j}}} + \frac{1}{16E_{C_c}} + \frac{1}{16E_{C_{g,p}}} \right]$$

$$\times \left[1 - \frac{E_t}{E_{C_c}} - \frac{E_t}{E_{C_{g,p}}} - (N - \min\{l, l'\}) \frac{E_t}{E_{C_{g,j}}} \right] \quad (\text{A12})$$

This final expression matches Refs. [26, 29] for an ordered array.

2. Collective modes.

Now, we define the collective modes for the fluxonium circuit, $\{\phi, \xi_1, \dots, \xi_{N-1}\}$ such that

$$\theta_m = \phi/N + \sum_{\mu} W_{\mu m} \xi_{\mu}, \quad (\text{A13})$$

and inversely,

$$\phi = \sum_{m=1}^N \theta_m, \quad \xi_{\mu} = \sum_{m=1}^N W_{\mu m} \theta_m. \quad (\text{A14})$$

Here, ϕ is called the superinductance mode or the *qubit* mode, while ξ_{μ} denote the parasitic modes indexed by $\mu \in \{1, \dots, N-1\}$ [29]. The matrix W is semi-orthogonal, with dimensions $(N-1) \times N$, and is given by $\sum_m W_{\mu m} W_{\nu m} = \delta_{\mu\nu}$. Its row sum is zero, $\sum_m W_{\mu m} = 0$. Thus, the following choice

$$W_{\mu m} = \sqrt{\frac{2}{N}} \cos \frac{\pi\mu(m-1/2)}{N}, \quad (\text{A15})$$

is observed in [29] to derive the Lagrangian for the symmetric circuit. The choice of these new variables highlights the collective modes describing the low-energy physics as illustrated in [27, 40, 41]. We now split the combined Lagrangian $\mathcal{L} = \mathcal{T} - \mathcal{U}$ into kinetic energy \mathcal{T} and potential energy \mathcal{U} terms in the basis of collective modes as,

$$\begin{aligned} \mathcal{T} = & \left[\left(\frac{\dot{\varphi}_{-1}}{E_{C_c}} + \frac{\dot{\varphi}_{-2}}{E_{C_c}} \right) \left(\frac{E_t}{8E_{C_c}} + \frac{E_t}{8E_{C_{g,p}}} \right) - \frac{\dot{\varphi}_{-2}}{8E_{C_c}} \right] \dot{\phi} \\ & + \sum_{l=1}^{N-1} (N-l) \frac{E_t}{8E_{C_{g,j}}} \left(\frac{\dot{\varphi}_{-1}}{E_{C_c}} + \frac{\dot{\varphi}_{-2}}{E_{C_c}} \right) \left(\dot{\phi}/N + \sum_{\mu} W_{\mu l} \dot{\xi}_{\mu} \right) \\ & + \sum_{l=1}^N \sum_{l'=1}^N \left(\dot{\phi}/N + \sum_{\mu} W_{\mu l} \dot{\xi}_{\mu} \right) \left(\dot{\phi}/N + \sum_{\mu} W_{\mu l'} \dot{\xi}_{\mu} \right) \\ & \times \left[\frac{N - \max\{l, l'\}}{16E_{C_{g,j}}} + \frac{1}{16E_{C_c}} + \frac{1}{16E_{C_{g,p}}} \right] \\ & \times \left[1 - \frac{E_t}{E_{C_c}} - \frac{E_t}{E_{C_{g,p}}} - (N - \min\{l, l'\}) \frac{E_t}{E_{C_{g,j}}} \right] \end{aligned} \quad (\text{A16})$$

$$\mathcal{U} = -E_{J_p} \cos(\phi) - \sum_{l=1}^N E_{J_j} \cos \left(\phi/N + \sum_{\mu} W_{\mu l} \xi_{\mu} \right) \quad (\text{A17})$$

3. Circuit modifications and assumptions

From here on, we define a sum over m, n as running from 1 to N , while the sum over μ, ν runs from 1 to

$N - 1$. To simplify the Lagrangian for the different circuits, we recall that $\sum_m W_{\mu m} = 0$ and the semi-orthogonal matrix condition $\sum_m W_{\mu m} W_{\nu m} = \delta_{\mu\nu}$, yielding the identities,

$$\sum_{n=1}^m W_{\mu n} = - \sum_{n=m+1}^N W_{\mu n} \quad (\text{A18})$$

$$\sum_{m=1}^N m W_{\mu m} = - \frac{c_\mu o_\mu}{\sqrt{2N} s_\mu^2} \quad (\text{A19})$$

$$\sum_{m=1}^N m^2 W_{\mu m} = \frac{c_\mu}{\sqrt{2N} s_\mu^2} [N(-1)^\mu - o_\mu] \quad (\text{A20})$$

where $o_\mu = \frac{1-(-1)^\mu}{2}$, $c_\mu = \cos \frac{\pi\mu}{2N}$, $s_\mu = \sin \frac{\pi\mu}{2N}$. We now simplify the kinetic energy and potential energy terms from Eqs. A16-A17 for the different circuits using these identities.

a. Linear approximation We discuss the simplification under the linear assumption on the parasitic modes μ . This includes only linear terms from the Taylor expansion of the cosine ($\cos x \sim 1 - \frac{x^2}{2}$) in Eq. A17, yielding (up to a constant term)

$$\mathcal{U} = E_{J_p} \cos(\phi) + \frac{E_{J_j}}{2N} \phi^2 + \frac{E_{J_j}}{2} \sum_{\mu} \xi_{\mu}^2 \quad (\text{A21})$$

$$= E_{J_p} \cos(\phi) + \frac{E_{J_j}}{2N} \phi^2 + \frac{E_{J_j}}{2} \sum_{\mu} \xi_{\mu}^2, \quad (\text{A22})$$

The potential energy of both circuits remains the same $\mathcal{U} = \mathcal{U}_{\text{sym}}$ (symmetric circuit) = $\mathcal{U}_{\text{asym}}$ (asymmetric circuit).

b. Symmetric circuit. For the circuit in Fig. 10(a), let the Lagrangian be denoted by $\mathcal{L}_{\text{sym}} = \mathcal{T}_{\text{sym}} - \mathcal{U}_{\text{sym}}$ and impose the conditions $\dot{\phi}_{-1} = 2\text{eV}$, $\dot{\phi}_{-2} = -2\text{eV}$.

$$\mathcal{T}_{\text{sym}} = -\frac{\dot{\phi}\text{eV}}{4E_{C_c}} + \left[(M_{00} + G_{00})\dot{\phi}^2 + 2 \sum_{\mu} (M_{0\mu} + G_{0\mu})\dot{\phi}\dot{\xi}_{\mu} + \sum_{\mu,\nu} (M_{\mu\nu} + G_{\mu\nu})\dot{\xi}_{\mu}\dot{\xi}_{\nu} \right]. \quad (\text{A23})$$

Here, M comes from the phase-slip junction and JJA, while G comes from the coupling and ground capacitances. These coefficients are given by:

$$M_{00} = \frac{1}{E_{C_{\text{tot}}}} + \frac{1}{NE_{C_j}}, M_{0\mu} = 0, M_{\mu\nu} = \frac{\delta_{\mu\nu}}{E_{C_j}} \quad (\text{A24})$$

$$G_{00} = \frac{1}{64E_t} \left[1 - \frac{2(N^2 - 1)E_t}{3NE_{C_{g,j}}} \right] \quad (\text{A25})$$

$$G_{0\mu} = -\frac{c_\mu o_{\mu+1}}{32E_{C_{g,j}}\sqrt{2N}s_\mu^2} \quad (\text{A26})$$

$$G_{\mu\nu} = \frac{1}{64E_{C_{g,j}}s_\mu^2} \left[\delta_{\mu\nu} - \frac{E_t}{E_{C_{g,j}}} \frac{2c_\mu c_\nu o_\mu o_\nu}{Ns_\nu^2} \right]. \quad (\text{A27})$$

Note that $C_{\text{tot}} = C_p + C$ is the total capacitance used for the qubit mode. The quantities $G_{00}, G_{0\mu}, G_{\mu\nu}$ contribute to the equations for the coupling strengths in the final Hamiltonian, while $M_{00}, M_{\mu\nu}$ contribute to the charging energies of the qubit and parasitic modes,

discussed in Sec. IV. We can see that only the parasitic modes with even index μ interact with the qubit since $G_{0\mu} = 0$ for $\mu \in 2\mathbb{Z} + 1$. The Hamiltonian for the asymmetric case, thus, will couple the odd modes (especially, parasitic mode $\mu = 1$) with the qubit [26].

c. Asymmetric circuit. For the circuit in Fig. 10(b), let the Lagrangian be denoted by $\mathcal{L}_{\text{asym}} = \mathcal{T}_{\text{asym}} - \mathcal{U}_{\text{asym}}$ and impose the conditions $\dot{\phi}_{-1} = 4\text{eV}$, $\dot{\phi}_{-2} = 0$. In addition, $C_c = 0$ on one end. The changes in the derivation include:

$$\dot{\phi}_0 = E_t \left(\frac{\dot{\phi}_{-1}}{E_{C_c}} - \sum_{l=1}^N \frac{\dot{\theta}_l}{E_{C_{g,p}}} - \sum_{i=1}^{N-1} (N-i) \frac{\dot{\theta}_i}{E_{C_{g,j}}} \right) \quad (\text{A28})$$

$$E_t = \left(\frac{1}{E_{C_c}} + \frac{N-1}{E_{C_{g,j}}} + \frac{2}{E_{C_{g,p}}} \right)^{-1} \quad (\text{A29})$$

$$\mathcal{L}_c + \mathcal{L}_g = \sum_{i=1}^N \frac{\dot{\phi}_{-1}\dot{\theta}_i}{E_{C_c}} \left(\frac{E_t}{8E_{C_{g,p}}} \right) + \sum_{i=1}^{N-1} \frac{\dot{\phi}_{-1}\dot{\theta}_i}{E_{C_c}} \frac{(N-i)E_t}{8E_{C_{g,j}}} + \sum_{l=1}^N \sum_{l'=1}^N \mathcal{G}_{ll'} \dot{\theta}_l \dot{\theta}_{l'}, \quad (\text{A30})$$

$$\mathcal{G}_{ll'} = \left[\frac{N - \max\{l, l'\}}{16E_{C_{g,j}}} + \frac{1}{16E_{C_{g,p}}} \right] \times \left[1 - \frac{E_t}{E_{C_{g,p}}} - (N - \min\{l, l'\}) \frac{E_t}{E_{C_{g,j}}} \right] \quad (\text{A31})$$

$$\mathcal{T}_{\text{asym}} = \frac{\dot{\phi}\text{eV}}{4E_{C_c}} \left[1 - \frac{E_t}{E_{C_c}} \right] - \frac{E_t}{2E_{C_{g,j}}E_{C_c}} \sum_{\mu} \frac{c_\mu o_\mu}{\sqrt{2N}s_\mu^2} \dot{\xi}_{\mu} \text{eV} + (M_{00} + G'_{00})\dot{\phi}^2 - 2(M_{0\mu} + G'_{0\mu})\dot{\phi}\dot{\xi}_{\mu} + \sum_{\mu,\nu} (M_{\mu\nu} + G_{\mu\nu})\dot{\xi}_{\mu}\dot{\xi}_{\nu} \quad (\text{A32})$$

$$G'_{00} = \frac{1}{64E_t} \left[1 - \frac{2(N^2 - 1)E_t}{3NE_{C_{g,j}}} - \frac{2E_t}{E_{C_c}} \right], \quad (\text{A33})$$

$$G'_{0\mu} = -\frac{c_\mu}{32E_{C_{g,j}}\sqrt{2N}s_\mu^2} \left[o_{\mu+1} - \frac{NE_t}{E_{C_c}} o_\mu \right]. \quad (\text{A34})$$

We can see that the parasitic modes with any index μ interact with the qubit as $G'_{0\mu} \neq 0 \quad \forall \mu$. The Hamiltonian for the asymmetric case, thus, will couple to all parasitic modes, even and odd (especially parasitic mode $\mu = 1$), with the qubit.

The derived Lagrangians provide the Hamiltonians for each circuit. Ref. [26] demonstrated that the symmetric circuit's Lagrangian, \mathcal{L}_{sym} , under certain assumptions on N , yields the Hamiltonian in Eqs. 1-3, where the coupling between the qubit and odd modes is zero. In contrast, we claim the asymmetric circuit's Lagrangian, $\mathcal{L}_{\text{asym}}$, results in a Hamiltonian with non-zero couplings between the qubit and all parasitic modes (odd and even). Thus, the symmetric case eliminates coupling to certain parasitic modes, including the lowest-frequency mode ($\mu = 1$), while the asymmetric case lacks this advantage. Given the parasitic frequency spectrum in Fig. 2(c) and the discussion in Sec. IV, the symmetric circuit's Floquet landscape is expected to exhibit fewer parasitic MISTs

than the asymmetric circuit. In this work, we are interested in identifying whether or not PMIST can be detrimental, even under the most conservative circuits where it may be avoided. Therefore, we focus exclusively on the symmetric circuit, as shown in Fig. 2(c) and Fig. 10(a) of the main text.

Appendix B: Undriven fluxonium circuit

In this appendix, we summarize the expressions for coupling strengths and charging energies used in Eqs. 1-3. We analyze the effect of variations in circuit parameters on these quantities. This analysis is used in Sec. IV to comment on the dependence of the parasitic effects captured in this work on circuit parameters. We also discuss the quantities related to the corresponding dispersive qubit Hamiltonians and give expressions for the dispersive coupling $\chi_{\phi\mu}$ used in Sec. III D.

1. Variation in charging energies and coupling strengths with circuit parameters

Here, we show the variations of the couplings and charging energies referenced in the main text, using the expressions derived in Ref. [26], with the number of junctions N and parasitic ground capacitance $C_{g,j}$, used in Sec. IV.

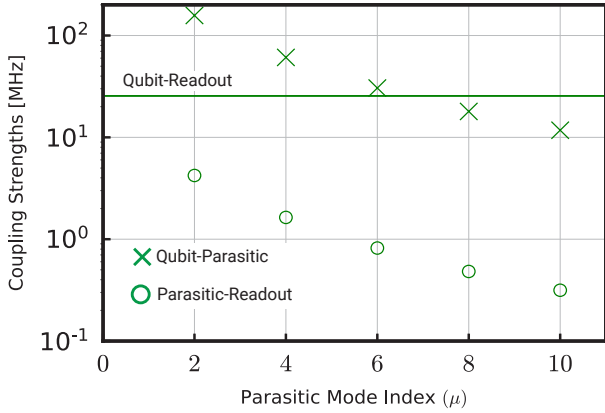


FIG. 11. **Absolute values of the coupling strengths.** $g_{\phi r}/2\pi$ (qubit-readout), $g_{\phi\mu}/2\pi$ (qubit-parasitic), $g_{\mu r}/2\pi$ (parasitic-readout), for various circuits. Coupling to odd parasitic modes is zero due to the symmetries of the circuit [26]. The parasitic modes $\mu \in \{2, 4, 6\}$ couple to the qubit more strongly than the readout.

1. Qubit charging energy ($E_{C_c}^\phi \hat{N}_\phi^2$): The target qubit charging energy is affected by parasitic effects since $\frac{1}{E_t} \neq 0$.

$$\frac{1}{E_c^\phi} = \frac{1}{4E_t} \left(1 - \frac{2}{3} \frac{N^2 - 1}{N} \frac{E_t}{E_{C_{g,j}}} \right) + \frac{1}{E_c} + \frac{1}{NE_{C_j}}.$$

2. Even parasitic-mode charging energy ($E_{c,\mu}^e$): The parasitic charging energy is crucial in deciding the parasitic-mode frequency ω_μ . Because only even parasitic modes (with index $\mu \in 2\mathbb{Z}$) couple to the qubit we will only give expressions

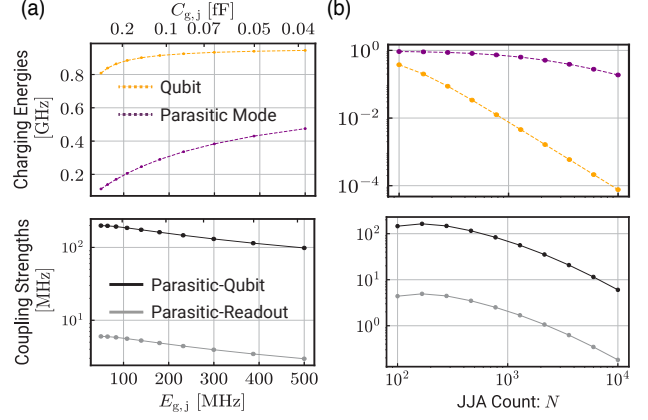


FIG. 12. **Dependence of coupling strengths and charging energies on circuit parameters.** (a) parasitic ground capacitance and (b) number of junctions in the array N . **(Top row)** The qubit charging energy $E_{C_c}^\phi$ decides the frequency ω_{01} and the parasitic charging energy $E_{c,\mu}^e$ decides the parasitic mode frequency for mode $\mu = 2$. **(Bottom row)** coupling strengths of the parasitic mode to readout ($g_{\mu r}/2\pi$) and qubit ($g_{\phi\mu}/2\pi$), respectively. All plots are obtained under linear JJA approximation.

for the even modes here.

$$\frac{1}{E_{c,\mu}^e} = \frac{1}{E_{C_j}} + \frac{1}{4E_{C_{g,j}} s_\mu^2}.$$

3. Qubit-readout Coupling ($g_{\phi r}$):

$$\frac{g_{\phi r}}{2\pi} = \frac{\tilde{E}_c^\phi}{E_{C_c}} N_{\phi,ZPF} N_{\mu,ZPF}.$$

4. Qubit-parasitic coupling ($g_{\phi\mu}$): The coupling strengths as shown in Fig. 7 induce all MIST effects. In particular, the parasitic-qubit coupling $g_{\phi\mu}$ is responsible for PMIST effects.

$$\frac{g_{\phi\mu}}{2\pi} = \sqrt{\frac{2}{N}} \frac{\tilde{E}_c^\phi \tilde{E}_{c,\mu}^{e,c\mu}}{E_{C_{g,j}} s_\mu^2} N_{\phi,ZPF} N_{\mu,ZPF}.$$

5. Readout-parasitic coupling ($g_{\mu r}$): The parasitic-readout coupling $g_{\mu r}$ only increases the population of the parasitic modes and is directly proportional to $g_{\phi\mu}$. We do not see any significant effects due to the $g_{\mu r}$ quantity in this work.

$$\frac{g_{\mu r}}{2\pi} = \frac{\tilde{E}_c^\phi \tilde{E}_{c,\mu}^{e,c\mu}}{4\sqrt{2N} E_{C_{g,j}} E_{C_c} s_\mu^2} N_{\mu,ZPF} N_{r,ZPF}.$$

Fig. 11 shows that the lowest three even modes $\mu = 2, 4, 6$ couple to the qubit more strongly than the readout. This observation is the backbone of our work; we find that because of this relatively large coupling strength, PMIST rates may be significant in fluxonium-based quantum computers. In Fig. 12, we show the dependence of charging energies and coupling constants on the number of junctions N as well as the ground capacitance $C_{g,j}$, while keeping all other parameters fixed. [42] We focus specifically on $g_{\phi\mu}$ and $E_{c,\mu}^e$ because the qubit-parasitic coupling is the main mechanism for PMIST, and the parasitic charging energy sets the parasitic frequency.

a. *Variation in coupling strength.* We find that achieving low $g_{\phi\mu}$ requires a low $C_{g,j}$ and a high N (see Fig. 12). Increasing N alters the qubit's target inductance, requiring a proportional increase in E_{J_j} to

maintain the inductive energy ($E_L = E_{J_j}/N$). However, E_{J_j} is limited to a finite value by fabrication constraints, which caps the maximum E_L . This supports the large- N approximation $\tilde{E}_{c,\mu} \approx 4E_{C_{g,j}}s_\mu^2$ (Eq. 11). Therefore, N can be optimized to reduce $g_{\phi\mu}$ while keeping E_L constant.

However, increasing N while keeping E_L and $E_{C_{g,j}}$ constant also lowers the parasitic charging energy (see Fig. 12). For large N and small μ , $\tilde{E}_{c,\mu}^e$ is

$$\tilde{E}_{c,\mu}^e \propto 1/N^2, \quad (\text{B1})$$

which decreases the parasitic mode frequency ω_{mu} with increasing N . A low parasitic mode frequency is generally unfavorable for reducing PMIST because it can lead to more allowed PMIST processes, as discussed in the next section. However, if ultimately the coupling $g_{\phi\mu}$ is negligible, even low-frequency parasitic modes will not contribute to PMIST effects.

b. Variation in parasitic charging energy. A higher parasitic charging frequency relative to the readout frequency reduces the likelihood of PMIST effects (see Sec. IV). We find that the parasitic charging energies increase with decreasing $C_{g,j}$ and N (see Fig. 12). From Eqs. 12-B1, in the large- N , small- μ limit, ω_μ^e is inversely proportional to N^2 and $C_{g,j}$, where $C_{g,j} [\text{fF}] = 19.4/E_{C_{g,j}} [\text{GHz}]$. Thus, reducing the parasitic ground capacitance $C_{g,j}$ increases the charging energy and raises the parasitic mode frequency, which is favorable.

A smaller N increases $g_{\phi\mu}$ but also raises the parasitic mode frequencies, widening the gap between ω_d and ω_μ , which is beneficial. However, decreasing N also introduces challenges, such as greater nonlinearity of parasitic modes and stronger coupling strengths. Conversely, a lower N that reduces $g_{\phi\mu}$ narrows the frequency gap, which is less favorable.

These considerations suggest that to minimize PMIST effects (for a given, fixed readout resonator frequency at which PMIST may occur), it is crucial to reduce the parasitic ground capacitance in the JJA. Simultaneously, the junction count N must be carefully optimized to balance parasitic frequencies and qubit-parasitic couplings, while respecting the assumptions of linearity of parasitic modes.

2. Fluxonium qubit Hamiltonian

We now discuss the parameters related to the fluxonium qubit Hamiltonian through a detailed consideration of its charge matrix elements and the dispersive shifts on the qubit induced by the parasitic modes and readout. The qubit Hamiltonian H_ϕ (see Eq. 2) is diagonalized in the Fock state basis, where we have used the standard bosonic operators.

$$\hat{x}_\phi = x_{\text{ZPF}}(\hat{a}_\phi + \hat{a}_\phi^\dagger) = \hat{N}_\phi/N_{\phi,\text{ZPF}} \quad (\text{B2})$$

and

$$\hat{p}_\phi = -ip_{\text{ZPF}}(\hat{a}_\phi - \hat{a}_\phi^\dagger) = \hat{\phi}/\phi_{\text{ZPF}}. \quad (\text{B3})$$

such that $[\hat{x}, \hat{p}] = i$.

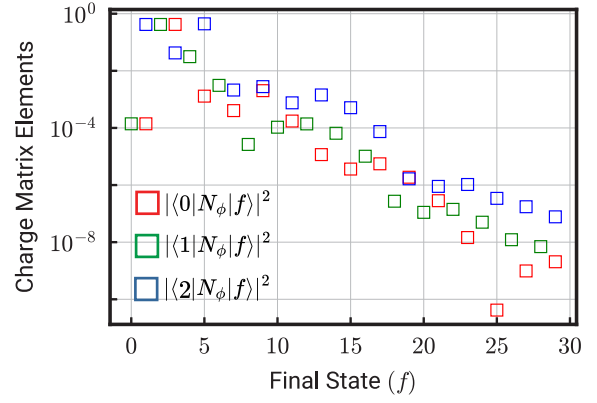


FIG. 13. **Charge matrix elements (squared) for the symmetric circuit.** The charge matrix elements between parity-conserving states are zero (points not seen in log plot) due to the symmetry of the cosine potential at $\varphi_{\text{ext}} = 0.5\Phi_0$, where Φ_0 is the flux quantum.

a. Charge matrix elements: Here, we calculate the charge matrix elements for the qubit mode using the approximations described in App. A. We observe that with increasing final state (f), the charge matrix elements for the ground and first two excited states follow a decreasing trend, approximately exponential. This exponential decrease to 10^{-10} motivates our truncation of the fluxonium potential up to 30 levels for the Floquet simulations of Sec. III.

b. Dispersive Hamiltonian Next, we extract the qubit parameters quoted in Table II, for example, the dispersive shift of the qubit due to the parasitic modes $\chi_{\phi\mu}$ and the readout mode $\chi_{\phi r}$ [26]. These variables were used to generate Fig. 6 in the main text. For this purpose, we first give the qubit Hamiltonian in the dispersive regime [26],

$$H/\hbar = \omega_q \sigma_z + \sum_{\mu} (\omega_{\mu} + \kappa_{\mu}) \hat{a}_{\mu}^{\dagger} \hat{a}_{\mu} + \omega_r \hat{a}_r^{\dagger} \hat{a}_r + (\chi_{\phi r} \hat{a}_r^{\dagger} \hat{a}_r + \sum_{\mu} \chi_{\phi\mu} \hat{a}_{\mu}^{\dagger} \hat{a}_{\mu}) \sigma_z \quad (\text{B4})$$

where $\omega_q = \omega_{01}$ is the qubit frequency, κ_{μ} is the Lamb shift on the parasitic mode, while all other variables follow the definitions used in Table II. In the main text, we have used the value of the dispersive shift ($\chi_{\phi\mu}$) due to the parasitic mode in Sec. III D, computed using the expression from Ref. [26]. For the parameters in Table I, we plot $\chi_{\phi\mu}$ for all parasitic modes of the symmetric circuit in Fig. 14. We also plot $\chi_{\phi r}$ for reference computed using the following expression (derivation not shown here),

$$\begin{aligned} \chi_{\phi r} = & 16g_{\phi r}^2 E_{C_R}^2 \sqrt{\frac{E_{L_R}}{32E_{C_R}}} \frac{2\epsilon_{01}}{\epsilon_{01}^2 - \omega_r^2} |\langle 0|\hat{p}_{\phi}|1\rangle|^2 \\ & + 16g_{\phi r}^2 E_{C_R}^2 \sqrt{\frac{E_{L_R}}{32E_{C_R}}} \left[\sum_l |\langle 0|\hat{p}_{\phi}|l\rangle|^2 \frac{\epsilon_{0l}}{\epsilon_{0l}^2 - \omega_r^2} \right. \\ & \left. - \sum_l |\langle 1|\hat{p}_{\phi}|l\rangle|^2 \frac{\epsilon_{1l}}{\epsilon_{1l}^2 - \omega_r^2} \right] \end{aligned} \quad (\text{B5})$$

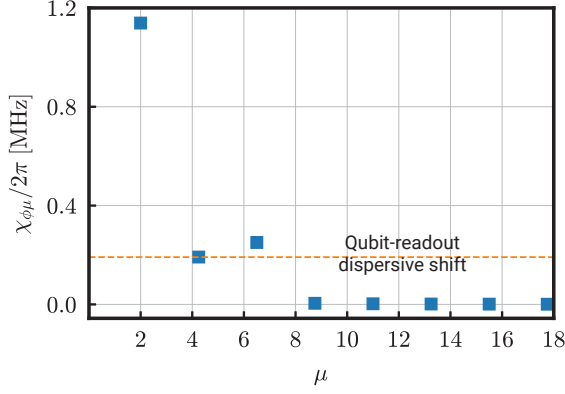


FIG. 14. **The dispersive shift ($\chi_{\phi\mu}$) induced on the qubit due to the parasitic mode μ .** The orange reference line represents the dispersive shift (\sim) induced by the readout resonator on the qubit ($\chi_{\mu r}$, see Eq. B5).

Appendix C: Driven fluxonium circuit

Here, we discuss several analysis techniques to study the effects of MIST used in this work. First, we discuss and justify the Hilbert space truncation, as well as approximations used for Floquet simulations in Sec. III. Next, we derive the semi-classical Hamiltonian $H_{s.c.}$ in Eq. 6 and discuss other details related to the Floquet simulations.

1. Approximations for numerical modeling

We use the following approximations in our work.

- **Restriction to $\mu = 2$.** We restrict our analyses to only include the lowest-frequency, even parasitic mode. This mode couples most strongly to the qubit and the readout as evident from Fig. 11(d). This assumption reduces the Hilbert space size for a feasible study.
- **Semi-classical drive approximation.** We treat the readout resonator classically as described in Refs. [20–23], eliminating the readout mode states from our numerical simulation. This approximation is again necessary to restrict the Hilbert space size to values feasible for numeric study.
- **Linear JJA approximation.** We assume that the parasitic modes are linear, due to the large $E_{J_j}/E_{C_j} \sim 200$ ratio. Nonlinear corrections to our results are beyond the scope of this work. For details on how nonlinear corrections affect different circuit energies, we direct the readers to [26].
- **Truncation.** We note that the charge matrix elements connecting the fluxonium qubit ground state to excited states decrease roughly exponentially with increasing excited state number (see Fig. 13). With this observation and our assumptions above, we truncate the Hilbert space

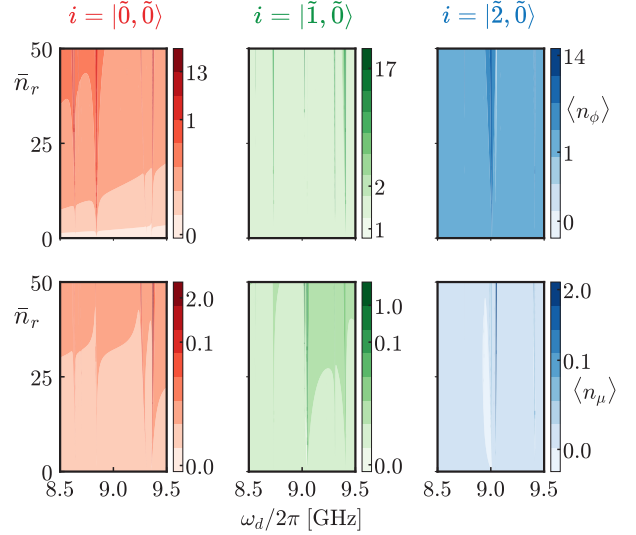


FIG. 15. **Truncation.** Floquet landscape of Fig. 3 computed using a Hilbert space of 30×10 is shown here. The two plots match in the fluxonium and parasitic levels which get excited at the expected frequencies, as quoted in Table. III. These plots are limited to only show transitions up to 20 levels in fluxonium and 5 levels in the parasitic mode for comparison with Fig. 3.

dimensions to 20×5 . That is, we assume 20 levels in the fluxonium qubit mode and 5 levels in the parasitic mode. We justify this truncation in Fig. 15 for all Floquet simulations by giving an analogous plot for Fig. 3 using a numerical simulation in Hilbert space of 30×10 .

Note that for the conclusions drawn in this paper, we are only interested in identifying the existence of PMIST processes. We do not claim to quantify how many such transitions can be present or to enumerate over the entire parameter space. Hence, with this truncation, we only examine the excitations in 0 – 20 levels in the fluxonium subspace in Figs. 3, 9, 7. However, in this appendix, we show the results of truncating the Hilbert space to 20×5 levels in the two modes and 30×10 , showing the convergence of the MIST results. Importantly, both simulations show no higher than excitation of $\bar{n}_\mu = 2$ in parasitic mode, further motivating our truncation.

2. Semi-classical approximation

In this appendix, we derive the semiclassical Hamiltonian $H_{s.c.}$ (see Eq. 4) used for the Floquet simulations. The fully-quantum driven readout fluxonium Hamiltonian is given by,

$$H_{\text{drive}} = \hat{H} \text{ (see Eq. 1)} - i\epsilon_d(\hat{a}_r - \hat{a}_r^\dagger)\cos\omega_d t \quad (\text{C1})$$

where ω_d is the drive frequency and $\epsilon_d \in \mathbb{R}$ is the drive strength. For the semi-classical approximation, we first use the rotating frame transformation $UH_{\text{drive}}U^\dagger - i\dot{U}U^\dagger$ under the unitary $U = e^{-i\hat{H}_r t} = e^{-i\omega_r \hat{a}_r^\dagger \hat{a}_r t}$. This transformation imposes $\hat{a}_r \rightarrow \hat{a}_r e^{-i\omega_r t} \equiv \hat{\tilde{a}}$. Now, in the interaction picture,

we have $\hat{H}_U \equiv U\hat{H}_{\text{drive}}U^\dagger + i\dot{U}U^\dagger$. Dropping terms which oscillate at a rate faster than $\omega_d = \omega_r$,

$$\begin{aligned} \hat{H}_U = & \hat{H}_\phi + \sum_{\mu \in 2\mathbb{Z}} \hat{H}_\mu + \frac{g_{\phi\mu}\hat{N}_\phi\hat{N}_\mu}{N_{\phi,\text{ZPF}}N_{\mu,\text{ZPF}}} - i\frac{\epsilon_d}{2}(\hat{a}_r + \hat{a}_r^\dagger) \\ & - i\frac{g_{\phi r}\hat{N}_\phi}{N_{\phi,\text{ZPF}}}(\hat{a}_r - \hat{a}_r^\dagger) - i\frac{g_{\mu r}\hat{N}_\mu}{N_{\mu,\text{ZPF}}}(\hat{a}_r - \hat{a}_r^\dagger) \end{aligned} \quad (\text{C2})$$

Now we go to the displaced frame $\hat{a}_r \rightarrow \hat{a}_r + \alpha$ via transformation under the unitary $U_\alpha = e^{-i\alpha(\hat{a}_r + \hat{a}_r^\dagger)}$ such that in the interaction picture we have $\hat{H}_U \rightarrow U_\alpha \hat{H}_U U_\alpha^\dagger + i\dot{U}_\alpha U_\alpha^\dagger$:

$$\hat{H}_U \rightarrow \hat{H}_\phi + \sum_{\mu \in 2\mathbb{Z}} \hat{H}_\mu + \frac{g_{\phi\mu}\hat{N}_\phi\hat{N}_\mu}{N_{\phi,\text{ZPF}}N_{\mu,\text{ZPF}}} \quad (\text{C3})$$

$$- i\frac{g_{\phi r}\hat{N}_\phi}{N_{\phi,\text{ZPF}}}(\hat{a}_r - \hat{a}_r^\dagger) - i\frac{g_{\mu r}\hat{N}_\mu}{N_{\mu,\text{ZPF}}}(\hat{a}_r - \hat{a}_r^\dagger) \quad (\text{C4})$$

$$- i\frac{g_{\phi r}\hat{N}_\phi}{N_{\phi,\text{ZPF}}}(\alpha e^{-i\omega_r t} - \alpha^* e^{i\omega_r t}) \quad (\text{C5})$$

$$- i\frac{g_{\mu r}\hat{N}_\mu}{N_{\mu,\text{ZPF}}}(\alpha e^{-i\omega_r t} - \alpha^* e^{i\omega_r t}) \quad (\text{C6})$$

$$- i\frac{\epsilon_d}{2}(\hat{a}_r + \hat{a}_r^\dagger) + \dot{\alpha}(\hat{a}_r + \hat{a}_r^\dagger) \quad (\text{C7})$$

We choose $\dot{\alpha} = i\frac{\epsilon_d}{2}$ s.t. $\text{Re}(\alpha(t)) = 0$ to remove the terms in Eq. C7, such that Eq. C6 takes the form,

$$\left[\frac{g_{\phi r}\hat{N}_\phi}{N_{\phi,\text{ZPF}}} + \frac{g_{\mu r}\hat{N}_\mu}{N_{\mu,\text{ZPF}}} \right] 2\alpha(t) \cos \omega_d t \quad (\text{C8})$$

Now, we go back to the lab frame and drop the terms associated with the quantum operators \hat{a}_r in Eqs. C4 while we replace $\alpha(t)$ with the mean value associated with the average number of photons in the readout at any time $\sqrt{\bar{n}_r(t)}$ in the term C8 to be used in \hat{H}_U [22], resulting in the final semi-classical form $H_{\text{s.c.}}$.

3. Floquet simulations

a. Stark shift: In this section, we compute the Stark-shifted eigenenergies that facilitate the prediction of an avoided crossing using a first-order perturbative approach, given \bar{n}_r, ω_r , and the charge-matrix elements. To observe a state transition, the primary requirements are large coupling, large charge-matrix elements, and small energy differences. The eigenenergies of the states in question are changed with an increase in the number of readout photons or, in this case, the drive strength. Let $|i\rangle$ be a state in the eigenspace of $H_{\text{int}} = H_\phi + H_{\mu=2} + \frac{g_{\phi\mu}}{N_{\phi,\text{ZPF}}N_{\mu,\text{ZPF}}}\hat{N}_\phi\hat{N}_\mu$. Following derivations in App. B, the Stark shift in the energy of state $|i\rangle$ at an average number of readout photons \bar{n}_r is given by

$$\begin{aligned} \chi_i(\bar{n}_r) = & 2\bar{n}_r \sum_f \omega_{if} \left[\frac{g_{\phi r} |\langle i|\hat{N}_\phi|f\rangle|^2}{N_{\phi,\text{ZPF}}(\omega_d^2 - \omega_{if}^2)} \right. \\ & \left. + \frac{g_{\mu r} |\langle i|\hat{N}_\mu|f\rangle|^2}{N_{\mu,\text{ZPF}}(\omega_d^2 - \omega_{if}^2)} \right] \end{aligned} \quad (\text{C9})$$

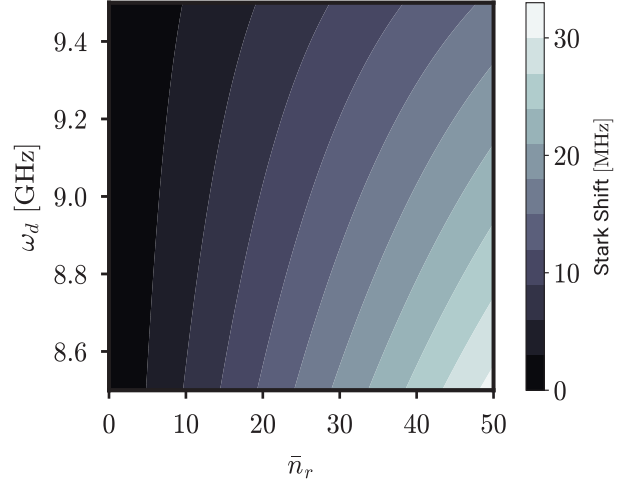


FIG. 16. **Stark shift in the ground state of fluxonium due to readout.** Values are computed using Eq. C9 for energy level $i = |\tilde{0}, \tilde{0}\rangle$. We have verified that the Stark shift on the excited energy levels $|\tilde{1}, \tilde{0}\rangle$ and $|\tilde{2}, \tilde{0}\rangle$ are also upper bounded by 50 MHz for the ranges of ω_d and \bar{n}_r considered in this plot.

Here $\omega_{if} = E_f - E_i$ denotes the energy difference in the eigenenergies of the state $|i\rangle$. The second term is much smaller than the first term, and hence $g_{\phi r}$ primarily governs this Stark shift.

b. Population exchange and quasienergies: Below we plot the population exchange and quasi-energy probabilities for all transitions captured in Fig. 3 and Table III for states $|\tilde{0}, \tilde{0}\rangle$ (see Fig. 21), $|\tilde{1}, \tilde{0}\rangle$ (see Fig. 22), and $|\tilde{2}, \tilde{0}\rangle$ (see Fig. 23). We comment on some special types of transitions explicitly here.

- Transition (2) has two crossings, one that takes place at $\bar{n}_r = 14$ and another at $\bar{n}_r = 48$. The states $|\tilde{4}, \tilde{2}\rangle$ and $|\tilde{14}, \tilde{2}\rangle$ hybridize first, and then the resulting state hybridizes with the computational state $|\tilde{0}, \tilde{0}\rangle$.
- Transitions (3,4) show a branch bunching scenario, as quoted in Ref. [23] for the case of positive detuning. Such branch bunching occurs when the drive frequency (ω_d) is equal to the transition frequency of two states i, j (ω_{ij}). However, in this case, we note that both branch bunching and crossings were observed in the negative detuning case. In the presence of a parasitic mode, there are multiple states ($|\tilde{i}, \tilde{\mu}\rangle$ and $|\tilde{j}, \tilde{\mu}\rangle$ for various μ) such that $\omega_d = \omega_{ij}$ is the resonant frequency for the observation of bunching between the two states.
- In transitions (9, 11, 12) the states do not return to the same population as the initial states. This is because we are plotting the bare fluxonium and parasitic mode operators $\langle \bar{n}_\phi \rangle, \langle \bar{n}_\mu \rangle$, as opposed to the dressed ones (which should show a recovery of the initial state). We make this choice to show the impact of PMIST effects on the bare fluxonium population.
- Finally, in transition (14), we again see two crossings. In the absence of qubit-parasitic cou-

pling $g_{\phi\mu}$, this transition is only carried out between $|17, \tilde{0}\rangle$ and $|\tilde{2}, \tilde{0}\rangle$. However, in the presence of parasitic modes, $|17, \tilde{0}\rangle$ hybridizes with $|\tilde{5}, \tilde{1}\rangle$ which then has a branch crossing with $|\tilde{2}, \tilde{0}\rangle$. Thus, in this case, we see that ignoring parasitic modes can lead to wrong state predictions, which could reduce qubit reset fidelity.

c. Landau-Zener probabilities: We compute the Landau-Zener probabilities in Sec. III C numerically using the quasienergies from the Floquet simulations, and analytically, using the Stark-shifted eigenenergies. In this case, we use a time-dependent readout photon number, where \bar{n}_r varies as $\bar{n}_r = 50(1 - e^{-\kappa t/2})^2$, to emulate change in readout photons from dissipation [21, 23]. The numerical calculations use the probability for Landau-Zener transitions given in [31], for an avoided crossing observed between states $|i\rangle, |f\rangle$ of

$$P_{\text{LZ}} = \exp \left[-\frac{\pi \Delta_{\text{ac}}^2}{2v} \right], \quad (\text{C10})$$

$$\text{where } v = \sqrt{2\Delta_{\text{ac}} \left| \frac{d^2 \epsilon_f}{d\sqrt{\bar{n}_r(t)}^2} \right|_{t_{\text{ac}}} \frac{d\sqrt{\bar{n}_r(t)}}{dt} \Big|_{t_{\text{ac}}}}. \quad (\text{C11})$$

Here, the variable ϵ_f is the numerically computed quasi-energy obtained from Floquet simulations, while Δ_{ac} refers to their quasi-energy difference at avoided crossing.

Appendix D: Alternative circuit parameters

Our analysis of PMIST so far has focused on systems where the fluxonium qubit frequency is $\omega_{01}/2\pi \sim 30$ MHz. Here, we consider how these processes change when one uses a larger qubit frequency $\omega_{01}/2\pi \sim 300$ MHz, as was recently realized in the experiment of Ref. [6]. For this purpose, we analyze a new set of circuit parameters (see Table V), inspired by Ref. [6].

N	φ_{ext}	E_{Jp}	E_{Cp}	E_{C}	E_{Jj}	E_{Cj}	$E_{\text{C}_{\text{g,j}}}$	$E_{\text{C}_{\text{g,p}}}$	E_{Cc}
102	$0.5\Phi_0$	6.20	9.74	1.11	81.6	0.74	194	1.94	19.40

TABLE V. **Circuit parameters for Fig. 17(a) inspired by Ref. [6].** All energies are given in GHz. Here $\Phi_0 = h/2e$ denotes the magnetic flux quantum. The capacitive energies $E_{\text{C}'} = \frac{19.4}{C'(\text{fF})}$ GHz are computed from the corresponding capacitances C' .

The parasitic mode frequency of the $\mu = 2$ mode is $\omega_{\mu=2}/2\pi = 15.50$ GHz. The coupling strengths are: $g_{\phi r}/2\pi = 37$ MHz, $g_{\phi\mu}/2\pi = 216$ MHz, $g_{\mu r}/2\pi = 6$ MHz. The plasma frequency is $\omega_{12}/2\pi = 5.40$ GHz. Even though the coupling strengths for these circuit parameters as shown in Fig. 18 are similar to the parameters studied in the main text (see Fig. 11), since the $\mu = 2$ parasitic mode is larger by about 4 GHz, we expect fewer PMIST processes for the drive frequency range analyzed in Fig. 3.

In addition, Fig. 19 shows that the charge matrix elements of the second circuit analyzed in Sec. D have

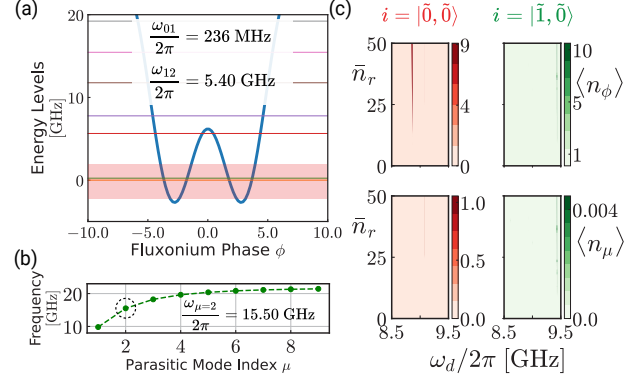


FIG. 17. **Floquet analysis with alternate JJA fluxonium parameters inspired by Ref. [6].** (a) Fluxonium energy spectrum. (b) Parasitic mode frequencies. (c) Floquet simulations for the branch analysis of the computational states. The Floquet figures are plotted in linear scale, unlike Fig. 3, making any streaks due to significantly weaker transitions unnoticeable. The truncation for these simulations uses the same justification and assumptions as App. C1.

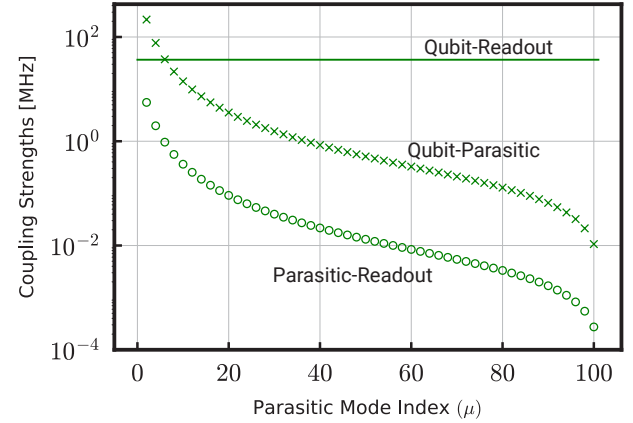


FIG. 18. **Magnitudes of the coupling strengths for parameters in Table V.** $g_{\phi r}/2\pi$ (qubit-readout), $g_{\phi\mu}/2\pi$ (qubit-parasitic), $g_{\mu r}/2\pi$ (parasitic-readout), for various circuits. Coupling to odd parasitic modes is zero due to the symmetries of the circuit [26]. The parasitic modes $\mu \in \{2, 4, 6\}$ couple to the qubit more or as strongly as the readout.

a faster decrease with increasing excited state levels. This could be indicative of the fact that such a circuit will see lower MIST effects as observed in Fig. 17(c). This also further supports our assumptions for numerical modeling to be the same as previous Floquet simulations as discussed in App. C1.

Fig. 17 shows that indeed, PMIST effects are comparatively less likely for this alternate circuit. The single PMIST process observed in the Floquet profile $|\tilde{0}, \tilde{0}\rangle \leftrightarrow |\tilde{4}, \tilde{1}\rangle$ occurs at $\bar{n}_r = 25$ and has the quasi-energy gap of $\Delta_{\text{ac}} = 0.13$ MHz at the avoided crossing. The explicit transition with quasi-energies is shown in Fig. 20. The reduced number of MIST effects in Fig. 17 compared to Fig. 3 can be attributed to the faster decreasing charge-matrix elements $|\langle i | \hat{N}_\phi | f \rangle|^2$ between computational basis levels $i = 0$ (and $i = 1$) and the higher fluxonium states (f) (compare Fig. 19

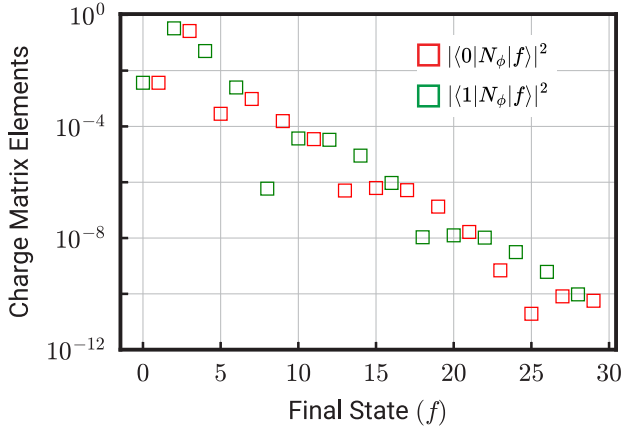


FIG. 19. **Charge matrix elements (squared) for parameters in Table V.** The charge matrix elements between odd-odd or even-even states are zero (points not seen in log plot) due to the symmetry of the cosine potential at $\varphi_{\text{ext}} = 0.5\Phi_0$, where Φ_0 is the flux quantum.

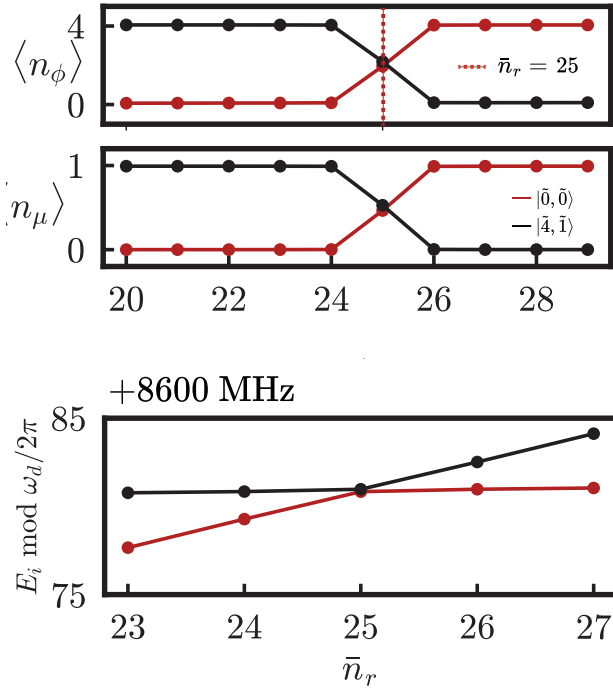
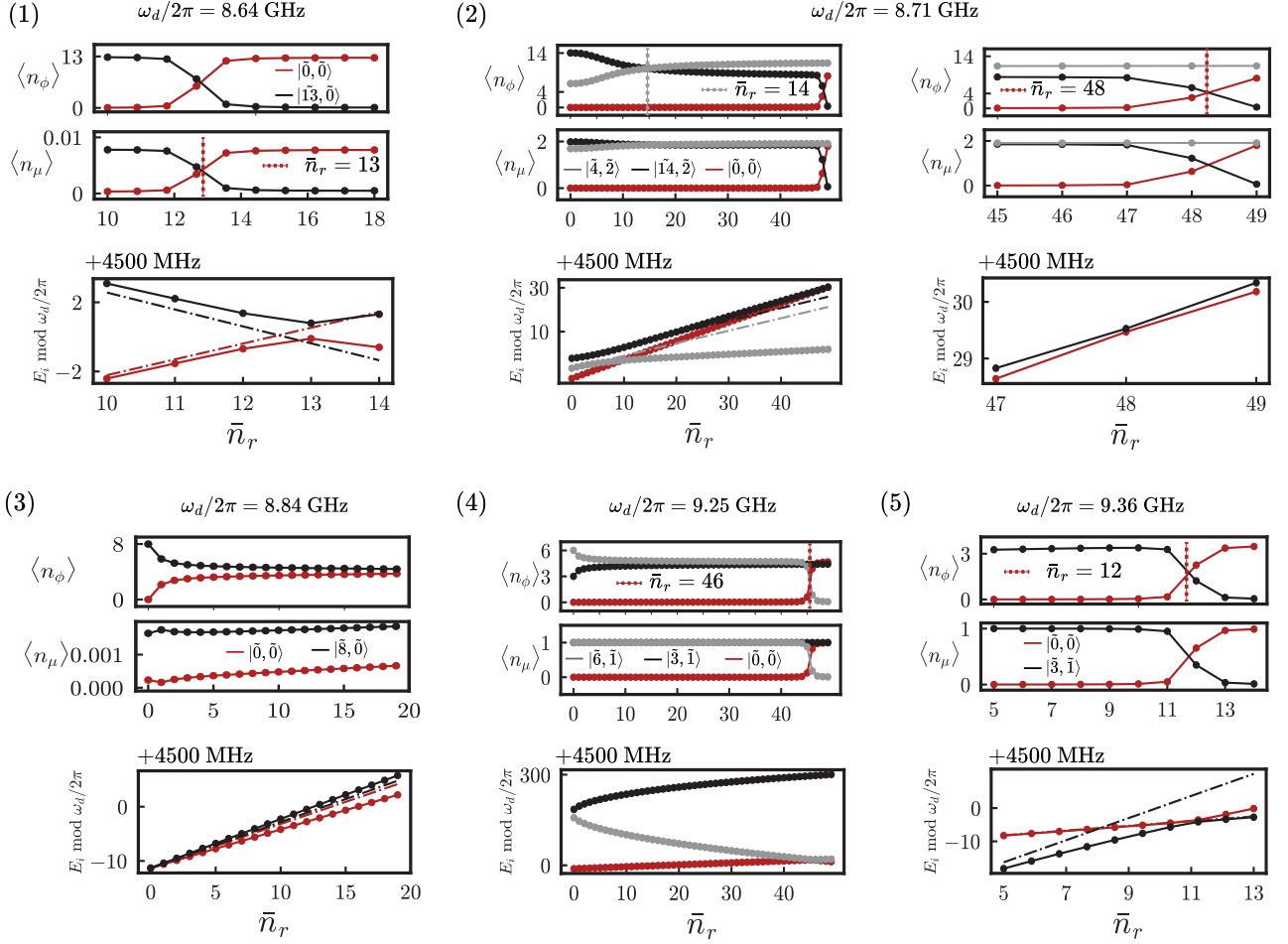


FIG. 20. **Examples of PMIST using transitions for the alternative circuit in Fig. 17(c) of Sec. D.** involving the states $|\tilde{0}, \tilde{0}\rangle \leftrightarrow |\tilde{4}, \tilde{1}\rangle$, with maximum overlap to the un-hybridized state $|k\rangle_\phi \otimes |n\rangle_{\mu=2}$. **Top row:** Qubit mode average occupation $\langle n_\phi \rangle$. **Middle row:** Parasitic mode average occupation $\langle n_\mu \rangle$. **Bottom row:** Quasi-energies (solid) from Floquet simulations showing avoided crossings. Plots are extracted from numerical data used in Fig. 3. The data points are connected by lines for visual aid.

with Fig. 13).

While the above results are promising, we stress that our analysis here considers a single specific PMIST process (i.e., involving the lowest-frequency array mode with the strongest qubit-parasitic coupling). Other less obvious processes may also play

a role, for example, PMIST due to parasitic modes $\mu \geq 4$. The Floquet simulation including all relevant parasitic modes is numerically intractable and hence warrants practical alternatives.



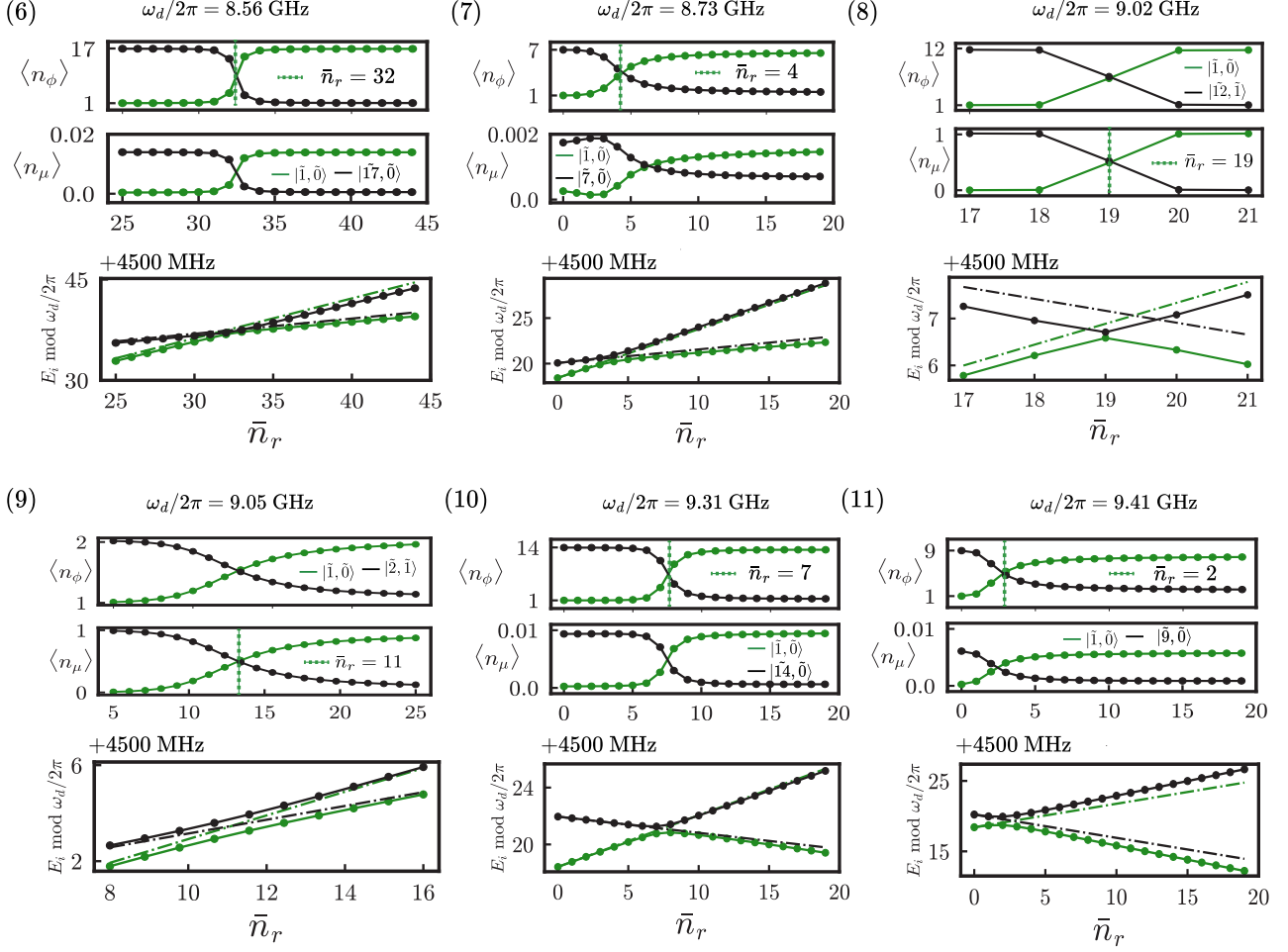


FIG. 22. **MIST processes from Table III involving the $|\tilde{1}, \tilde{0}\rangle$ state.** The figure numbering indicates the row index in Table III. (Top row) Fluxonium subspace $\langle n_\phi \rangle$. (Middle) Parasitic mode subspace $\langle n_\mu \rangle$. (Bottom) Stark-shifted eigenenergies (dashed) and quasi-energies (solid) from Floquet simulations correspond to the initial state i as per the legend. The y-axis for this plot is in MHz. Floquet results are extracted from numerical data used for Fig. 3.

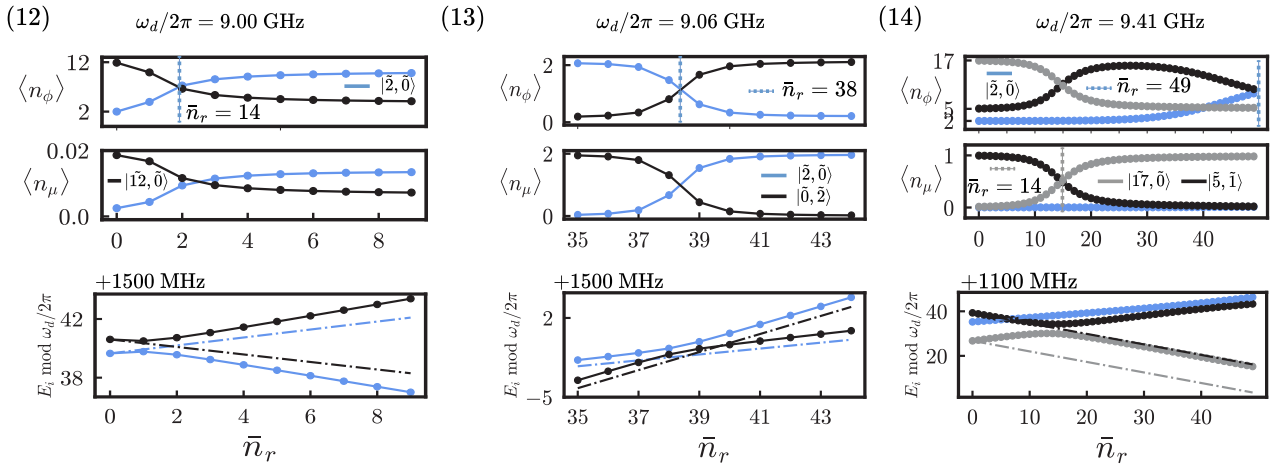


FIG. 23. **MIST processes from Table III involving the $|\tilde{2}, \tilde{0}\rangle$ state.** The figure numbering indicates the row index in Table III. (Top row) Fluxonium subspace $\langle n_\phi \rangle$. (Middle) Parasitic mode subspace $\langle n_\mu \rangle$. (Bottom) Stark-shifted eigenenergies (dashed) and quasi-energies (solid) from Floquet simulations correspond to the initial state i as per the legend. The y-axis for this plot is in MHz. Floquet results are extracted from numerical data used for Fig. 3.

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- [38] Note that there are downward transitions from $|2\rangle_\phi$ (blue dots) to the states $|1\rangle_\phi$ (green line) and $|0\rangle_\phi$ (red line) in the fluxonium subspace in the presence of parasitic modes. An example is captured by transition 13 of Table III.
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